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General Description

The MAX25069 is a highly integrated TFT power supply and LED backlight driver IC for automotive TFT-LCD applications. This IC integrates one boost converter, one inverting buck-boost converter, two gate-driver supplies, and a boost/SEPIC controller that can power 1 to 6 strings of LEDs in the display backlight.

The source-driver power supplies consist of a boost converter which can provide up to +18V in unipolar mode and an inverting buck-boost converter that can generate a voltage down to -10.5V. The AVDD output can deliver up to 300mA at 13.5V, while NAVDD can provide up to 200mA. The positive source-driver supply-regulation voltage (V_{AVDD}) is set using internal NV memory or through I²C. The negative source-driver supply voltage (V_{NAVDD}) is always tightly regulated to -V_{AVDD}. The source-driver supplies operate from an input voltage between 2.65V and 5.5V.

The gate-driver power supplies consist of regulated charge pumps that generate up to +31.5V and down to -18V and can deliver up to 15mA each.

The IC features a 6-string LED driver with input switch control (NGATE) that can power up to 6 strings of LEDs with 150mA (max) of current per string.

Logic-controlled and I²C-controlled pulse-width modulation (PWM) dimming are included, with minimum pulse widths as low as 300ns and the option of phase shifting the LED strings with respect to one another. When phase shifting is enabled, each string is turned on at a different time, reducing the input and output ripple, as well as audible noise. With phase shifting disabled, the current sinks turn on simultaneously and parallel connection of current sinks is possible.

The startup and shutdown sequences for all power domains are controlled using one of the eight preset modes, which are selectable using internal nonvolatile memory or through the I^2C interface.

The MAX25069 is available in a 7mm x 7mm, 48-pin TQFN package with an exposed pad, and operates over the -40°C to +125°C ambient temperature range.

Applications

- Automotive Dashboards
- Automotive Central Information Displays
- Automotive Head-Up Displays
- Automotive Navigation Systems

Benefits and Features

- 4-Output TFT-LCD Bias Power
 - 2.65V to 5.5V Input for the TFT-LCD Section
 - Integrated 420kHz or 2.1MHz Boost and Buck-Boost Converters
 - Positive and Negative 15mA Gate Voltage Regulators with Adjustable Output Voltage (Tripler/ Inverting Doubler)
 - Flexible Sequencing
 - Undervoltage Detection on All Outputs
 - Low-Quiescent-Current Standby Mode
- 6-Channel, 36V LED Backlight Driver
 - NGATE Control for External nMOSFET Series
 Switch
 - Programmable nMOSFET Current Limit
 - Up to 150mA Current per Channel
 - 4.5V to 36V Input Voltage Range, 3V Operation after Startup
 - Integrated Boost/SEPIC Controller (400kHz to 2.2MHz with Synchronization)
 - Dimming Ratio 16,667:1 at 200Hz
 - Adaptive Voltage Optimization to Reduce Power Dissipation in the LED Current Sinks
 - Open-String, Shorted-LED, and Short-to-GND Diagnostics
- Low EMI
 - Phase-Shift Dimming of LED Strings
 - Spread Spectrum on LED Driver and TFT
 - Selectable Switching Frequency
- I²C Interface for Control and Diagnostics
 - Fault Indication through the FLTB Pin and I²C
 Nonvolatile Configuration Memory
- Overload and Thermal Protection
- -40°C to +125°C Ambient Temperature Operation
- 48-Pin, 7mm x 7mm TQFN Package with Exposed Pad
- AEC-Q100 Grade 1

<u>Ordering Information</u> appears at end of data sheet.

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Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Simplified Block Diagram



Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

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Absolute Maximum Ratings

BATT, OUT1-6, BSTMON to GND	0
NGATE to BATT	+6V
NGATE to GND	
IN, INN, FLTB, PFO, DIM, EN, SD	A, SCL to GND0.3V to +6V
NDRV, NDRVS to GND	0.3V to V5 + 0.3V
TEMP, MODE, CSP, COMP, IREF	F, RT, ADD to GND0.3V to
	V18 + 0.3V
HVINP to GND	0.3V to +22V
LXP to GND	0.3V to +30V
LXP1/2, PGND1/2 RMS Total Cur	rent Rating 2.4A
V5 to GND	0.3V to MIN (6, HVINP + 0.3)V
V18 to GND	0.3V to MIN (2.2, IN + 0.3)V
PGVDD, AVDD, DP, DN to GND	0.3V to HVINP + 0.3V
LXN to INN	
LXN, INN RMS Current Rating	
VG _{ON} to GND	

V _{PROG} to GND	0.3V to +12V
NAVDD to GNDVV18	- 16V to V _{V18} + 0.3V
VG _{OFF} to GNDV _{V18}	- 22V to V _{V18} + 0.3V
GND to PGND1, PGND2, PGND3	0.3V to +0.3V
GND to LGND	0.3V to +0.3V
GND to CPGND	0.3V to +0.3V
GND to CSN	0.3V to +0.3V
Continuous Power Dissipation (T _A = +70°C	3)
48-Pin TQFN-EP (derate 43mW/°C abov	ve +70°C), (multilayer
board)	3433mW
Operating Temperature Range	40°C to +125°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

48 TQFN

Package Code	T4877+9C				
Outline Number	<u>21-0144</u>				
Land Pattern Number	<u>90-0464</u>				
Thermal Resistance, Four-Layer Board:					
Junction to Ambient (θ_{JA})	23.3°C/W				
Junction to Case (θ_{JC})	1°C/W				

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to <u>www.maximintegrated.com/thermal-tutorial</u>.

Electrical Characteristics

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
INPUT SUPPLY						
IN, INN Voltage Range	V _{IN_RNG}		2.65		5.5	V
IN UVLO Threshold, Rising	V _{IN_UVLOR}	IN voltage rising	2.4	2.5	2.57	V
IN UVLO Threshold, Falling	VIN_UVLOF		2.3		2.5	V
PFO Threshold	V _{PFO}	IN falling, pfo_th = 0, PFO output goes low	2.4	2.5	2.6	V
Total Input Shutdown Current (IN + INN + HVINP + LXP)	IIN_SHDN	EN = GND, T _A = +25°C		3.5	15	μA

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Electrical Characteristics (continued)

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
IN + INN Quiescent Current	I _{IN_Q}	V _{EN} = 3.3V, no swi	tching		2	4	mA
V18 REGULATOR							
V18 Output Voltage	V _{V18_ACC}	No load on V18		1.72	1.8	1.88	V
V18 Current Limit	I _{LIM_V18}	V _{V18} = 1V		50			mA
V18 Undervoltage Lockout	V _{V18} _UVLO	V18 voltage rising		1.6	1.65	1.7	V
V18 Undervoltage Hysteresis	V _{V18_UVLO_H} YS				150		mV
TFT POWER SECTION /	OSCILLATOR						
	f _{BOOSTH}	f_{SW} bit = 0, dither d	lisabled	1950	2100	2250	ku-
	f BOOSTL	f _{SW} bit = 1, dither c	lisabled	380	420	460	KEIZ
Frequency Dither	f BOOSTD				±6		%
TFT POWER SECTION /	BOOST REGUL	ATOR					
HVINP Output Voltage	VINGNE	dis_navdd = 0		4.9		10.5	v
Range	* HVINP	dis_navdd = 1		11.7		18	v
AVDD Adjustment Step Size	V _{STEP}				0.1		V
AVDD Output Regulation	V _{AVDD_ACC}	avdd[5:0] = 0x1A, c	lis_navdd = 0	6.66	6.8	6.94	V
LXP Maximum Duty	D	420kHz switching f	requency	91.75	95		0/
Cycle	DLXP_MAX	2.1MHz switching f	2.1MHz switching frequency		95		7 %
Low-Side Switch On- Resistance	R _{ON_LS_LXP}	I _{LXP} = 0.1A			0.1	0.2	Ω
LXP Leakage Current	ILEAK_LXP	$V_{EN} = 0V, V_{LXP} = 1$	15V			6	μA
	ILIMPHB	dia navida - 0	Duty cycle = 80%, Lxp_Lim_Low = 0	1.5	1.8	2.1	
	ILIMPLB	dis_navdd = 0	Duty cycle = 80%, Lxp_Lim_Low = 1		1		
	ILIMPHU	dia navdd - 1	Duty cycle = 80%, Lxp_Lim_Low = 0	2.3	2.7	3.2	A
	ILIMPLU		Duty cycle = 80%, Lxp_Lim_Low = 1		1.35		
Soft-Start Period	tBOOST_SS	Current-limit ramp			5		ms
TFT POWER SECTION /	INVERTING REG	GULATOR					
LXN Maximum Duty Cycle	D _{LXN_MAX}	f _{SW} = 420kHz or 2.	1MHz	91.75	95		%
V _{AVDD} + V _{NAVDD} Regulation Voltage	V _{NAVDD_} AVD D_REG	V_{INN} = 2.65V to 5.5V, V_{AVDD} = 6.8V, 1mA < I _{NAVDD} < 200mA, I _{AVDD} = same load as NAVDD		-34	0	34	mV
LXN On-Resistance	R _{ON_LXN}	I _{LXN} = 0.1A			0.25	0.5	Ω
LXN Leakage Current	ILXN LEAK	$V_{LXN} = V_{NAVDD} =$	-6.8V, T _A = +25°C			20	μA

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Electrical Characteristics (continued)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
I XN Current Limit	ILIMNL	Duty cycle = 80%, Lxp_Lim_low = 1	0.6	0.8		٨	
	ILIMNH	Duty cycle = 80%, Lxp_Lim_low = 0	1.55	1.9	2.25		
Soft-Start Period	t _{INV_} ss	Current-limit ramp		5		ms	
TFT POWER SECTION / CHARGE-PUMP REGULATORS							
PGVDD Operating Voltage Range	V _{PGVDD}		4.9		V _{HVINP}	V	
HVINP-PGVDD Threshold for VG _{ON} Startup	V _{HVINP-} PGVDD	V _{HVINP} = 5V	360	520	680	mV	
High-Side DP/DN Current Limit	I _{DR_HS}	V_{HVINP} = 6.8V, V_{DP} = V_{DN} = 3V	95			mA	
Low-Side DP/DN Current Limit	I _{DR_LS}	$V_{DP} = V_{DN} = 3V$	95			mA	
High-Side DP/DN On- Resistance	R _{DR_HS}	$I_{DP} = I_{DN} = -20$ mA, $V_{PGVDD} = V_{HVINP} = 6.8$ V		5	8	Ω	
Low-Side DP/DN On- Resistance	R _{DR_LS}	$I_{DP} = I_{DN} = 20 \text{mA}$		3	6	Ω	
VG _{ON} Unipolar Voltage Range	VG _{ON_RNG}	dis_navdd = 1	12.6		31.5	V	
VG _{ON} Bipolar Voltage Range	VGON _{RNGB}	dis_navdd = 0	8.4		21	V	
VG _{ON} Unipolar Adjustment Step Size	LSB _{VGON}	dis_navdd = 1		0.3		V	
VG _{ON} Bipolar Adjustment Step Size	LSB _{VGONB}	dis_navdd = 0		0.2		V	
VG _{ON} Internal Feedback Resistor Value	R _{VGON}		700		1250	kΩ	
VG _{ON} Output Voltage Accuracy	ACC _{VGON}	0x16h setting	-2		2	%	
VG _{OFF} Voltage Range	VG _{OFF_RNG}		-18		-4	V	
VG _{OFF} Adjustment Step Size	LSB _{VGOFF}			0.25		V	
VG _{OFF} Output-Voltage Accuracy	ACC _{VGOFF}	0x16h setting	-3		+3	%	
TFT POWER SECTION /	SEQUENCE SW	/ITCHES					
AVDD Switch On- Resistance	R _{ON_AVDD}	V _{HVINP} = 6.8V, I _{AVDD} = -100mA		0.9	1.6	Ω	
AVDD Switch Current Limit	ILIM_AVDD		400	500	650	mA	
AVDD Discharge Resistance	R _{AVDD_} DIS	AVDD disabled, V _{V18} > V _{V18_UVLO}		1.2		kΩ	
PGVDD On-Resistance	R _{ON_PGVDD}	(HVINP - PGVDD), I _{PGVDD} = 10mA		2.5	5	Ω	
PGVDD Current Limit	ILIM_PGVDD	V _{PGVDD} = 3V, V _{HVINP} = 6.8V	70	100		mA	

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Electrical Characteristics (continued)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
VG _{ON} Discharge Resistance	R _{DIS_VGON}		2	3	4	kΩ
VG _{OFF} Discharge Current	IDIS_VGOFF			1.5		mA
NAVDD Discharge Resistance	R _{NAVDD_DIS}	NAVDD disabled, V _{V18} > V _{V18_UVLO}		1		kΩ
TFT POWER SECTION /	TFT FAULT PRO	DTECTION				
Fault Timeout	^t FAULT	tfault[1:0] = 10		60		ms
Fault Retry Time	t _{auto}	tretry[1:0] = 10 or 11		1.9		S
FLTB Output Frequency		Stand-alone mode only	0.88	1	1.12	kHz
HVINP/AVDD Undervoltage Fault Threshold	THR _{UV}	Relative measurement between HVINP and AVDD	81	85	89	%
HVINP/AVDD Short- Circuit Fault Threshold	THR _{SHRT}		36	40	44	%
NAVDD Undervoltage Fault Threshold	THR _{UV}	Of AVDD regulation voltage, NAVDD rising	81	85	89	%
NAVDD Short-Circuit Fault Threshold	THR _{SHRT}	Of AVDD regulation voltage, NAVDD voltage rising	36	40	44	%
VG _{ON} Undervoltage Fault Threshold	THR _{UV}	Of set value, VG _{ON} voltage falling	81	85	89	%
VG _{OFF} Undervoltage Fault Threshold	THR _{UV}	Of set value, VG _{OFF} voltage rising	78		88	%
Short-Circuit Fault Delay		After completion of soft-start		10		μs
LED BACKLIGHT DRIVE	R					
BATT Operating Voltage Range	V _{BATT}		4.5		36	V
BATT Operating Voltage Range after Startup	V _{BATT}	Maximum duration 100ms	3		36	V
BATT Quiescent Supply Current	I _{Q_BATT}			5	10	μA
BATT Shutdown Supply Current	IBATT_SHDN	V _{EN} = 0V, T _A = +25°C, typical application circuit		1	3	μA
BATT Undervoltage Lockout, Rising	V _{BATT_UVR}	BATT voltage rising	4.15	4.29	4.4	V
BATT Undervoltage Lockout, Falling	VBATT_UVF	BATT voltage falling	2.77	2.9	2.95	V
BATT Threshold for	V _{BATT_LVF}	BATT voltage falling	5.35	5.5	5.65	
Low-Voltage Operation Mode	V _{BATT_LVR}	BATT voltage rising	5.55	5.72	5.85	V
LED BACKLIGHT DRIVE	R / V5 REGULA	TOR				
V5 Output Voltage	V_{V5}	5.75V < V _{HVINP} < 18V, I _{V5} = 1mA to 10mA	4.8	5	5.2	V
V5 Dropout Voltage	V _{V5_DRP}	V _{HVINP} = 4.9V, I _{V5} = 5mA		0.05	0.12	V

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Electrical Characteristics (continued)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
V5 Undervoltage	V _{V5_UVLOR}	V5 voltage rising	3.8	3.9	4.1	V
Lockout	V _{V5_UVLOF}	V5 voltage falling	3.6	3.7	3.8	V
V5 Short-Circuit Current Limit	I _{V5_SC}	V5 shorted to GND	50			mA
LED BACKLIGHT DRIVER / NGATE OUTPUT						
NGATE Output Voltage	V _{NGATE}	Above V _{BATT} , 3.3V < V _{BATT} < 33V, I _{NGATE} = 1µA	4.3	5.25	6	V
NGATE Source Current	I _{NG_SO}	V _{NGATE} = V _{BATT}	30	50		μA
NGATE Sink Current	I _{NG_SINK}		0.4	0.7		mA
NGATE Output Voltage at High Input Voltage	V _{NGATE_} HV	Above V _{BATT} , V _{BATT} > 35.5V, I _{NGATE} = 1μA	-0.3		0	V
BATT HV Comparator Threshold	V _{LD_THR}	BATT voltage rising	33		35.5	V
BATT HV Comparator Hysteresis	V _{LD_HYS}			0.7		V
NGATE Start Delay	^t NG_DEL	Delay between NGATE charge-pump turning on and BSTMON rising		2	2.2	ms
LED BACKLIGHT DRIVE	R / RT OSCILLA	TOR				
Switching Frequency Range	fsw_rt	Frequency dithering disabled	400		2200	kHz
Oscillator Frequency Accuracy		I _{RT} = 13.85μA (f _{SW} = 400kHz), I _{RT} = 75μA (f _{SW} = 2200kHz)	-10		10	%
Boost Converter Maximum Duty Cycle, High Frequency		1.3MHz to 2.2MHz	89	91	94	%
Boost Converter Maximum Duty Cycle, Low Frequency		f _{SW} = 400kHz to 1.3MHz	94		98	%
Boost Minimum On- Time				60		ns
Frequency Dither, High Setting	SSHI	bl_ssl = 0		±6		%
Frequency Dither, Low Setting	SSLO	bl_ssl = 1		±4		%
RT Output Voltage	V _{RT}	$R_{RT} = 65k\Omega \text{ or } R_{RT} = 10k\Omega$	0.875	0.9	0.925	V
Sync Threshold	V _{RT_SYNC}	V _{RT} rising	0.77		0.84	V
Sync Frequency Duty- Cycle	D _{SYNC}			50		%
Sync Frequency Range			400		2200	kHz
LED BACKLIGHT DRIVE	R / SLOPE CON	IPENSATION				
Peak Slope- Compensation Current Ramp per Cycle	ISLOPE	Current ramp added to CS	42	50	60	μA

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Electrical Characteristics (continued)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
LED BACKLIGHT DRIVE	R / CURRENT-L	IMIT COMPARATOR	-1				
	V _{CSP-CSNL}	bl_ilim = 1	275	300	325		
CSP Inreshold Voltage	V _{CSP-CSN}	bl_ilim = 0	380	410	440	mv	
CSP Threshold Voltage During Low Voltage	V _{CSP_LV}	$V_{BATT} < V_{BATT_LVF}, V_{BATT}$ falling	560	600	640	mV	
CSP Input Current	I _{CSP}	V _{EN} = 0V, V _{CSP} = 0.4V			+1	μA	
LED BACKLIGHT DRIVE	R / ERROR AMP	PLIFIER					
OUT_ Regulation High Threshold	V _{THH}	V _{OUT} _rising	/ _{OUT_} rising 0.825 0.85				
OUT_ Regulation Low Threshold	V _{THL}	V _{OUT_} falling	0.55	0.58	0.61	V	
Transconductance	Ям		410	630	890	μS	
COMP Sink Current	ICOMP_SINK	V _{COMP} = 1V	270	380	500	μA	
COMP Source Current	ICOMP_SRC	V _{COMP} = 1V	270	380	500	μA	
LED BACKLIGHT DRIVE	R / MOSFET DR	IVER					
NDRV On-Resistance	R _{NDRV_LS}	V _{V5} = 5V, I _{NDRV} = 100mA		1.2	2	0	
	R _{NDRV_HS}	V _{V5} = 5V, I _{NDRV} = -100mA	1.5 3			32	
NDRV Rise Time	t _{NDRV_R}	C _{NDRV} = 1nF, (<u>Note 2</u>)		8		ns	
NDRV Fall Time	t _{NDRV_F}	C _{NDRV} = 1nF, (<u>Note 2</u>)		8		ns	
NDRVS Input Logic-Low	VIL_NDRVS	V _{NDRVS} falling		2	2.4	V	
NDRVS Input Logic- High	V _{IH_NDRVS}	V _{NDRVS} rising	2.55	3.3		V	
NDRVS Input Current	INDRVS	V _{NDRVS} = 5V		60		μA	
LED BACKLIGHT DRIVE	R / LED CURRE	NT SINKS					
IREF Output Voltage	V _{IREF}	I _{IREF} = 40μA	0.86	0.88	0.9	V	
	I _{OUT} _	iset[6:0] = 0x7F, 150mA setting	145	150	154		
Full-Scale OUT_ Output	I _{OUT100}	iset[6:0] = 0x4D, 100mA setting	97	100	103]	
Current	I _{OUT50}	iset[6:0] = 0x1B, 50mA setting	48	50	52		
	I _{OUT23}	iset[6:0] = 0x00, 23mA setting	21.5	23	25.2		
Current Regulation Between Strings	IOUT_MATCH1 50	I _{OUT} = 150mA, design target	-2		+2	%	
Current-Setting Resolution	IOUT_LSB			1		mA	
		V_{OUT} = 36V, DIM = 0, all OUT_ pins shorted together, T _A = +25°C		0.1	5	μA	
	'OUT_LEAK	V _{OUT} = 36V, DIM = 0, all OUT_ pins shorted together		0.1	15	μA	
OUT_ Minimum Pulse Width				300		ns	
OUT_ Minimum Negative Pulse Width				90		ns	

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Electrical Characteristics (continued)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS			
I _{OUT} _Rise Time	IOUT_TR	I _{OUT} = 150mA, 10% to 90% I _{OUT}		150		ns			
I _{OUT} _Fall Time	IOUT_TF	I _{OUT} = 150mA, 90% to 10% I _{OUT}		20		ns			
LED BACKLIGHT DRIVER / DIM, ADIM INPUTS									
DIM Frequency Range			90		50000	Hz			
DIM Sampling Frequency				20		MHz			
ADIM Input Frequency Range			10		100	kHz			
LED BACKLIGHT DRIVE	R / LED FAULT	DETECTION							
LED Short-Detection	VTHSHRT	I ² C mode, bit configuration = 11 (00: short detection disabled), default value in stand-alone mode	7.7	8	8.3	V			
Inresnoid	moniti	I ² C mode, led_short_th[1:0] = 10	5.75	6	6.25				
		I ² C mode, led_short_th[1:0] = 01	2.8	3	3.2				
OUT_ Check-LED- Source Current	IOUT_CKLED	V _{OUT} _= 0.5V	50	60	70	μA			
OUT_ Short-to-GND Detection Threshold	V _{OUT_GND}	V _{OUT_} falling	230	250	270	mV			
OUT_Unused-Detection High Threshold	V _{OUT_UN}		0.8	0.85	0.9	V			
OUT_ Open-LED- Detection Threshold	V _{OUT_OPEN}		230	250	270	mV			
Shorted-LED-Detection Flag Delay	^t SHRT			6.8		μs			
LED BACKLIGHT DRIVE	R / OVERVOLTA	AGE AND UNDERVOLTAGE PROTECTION							
BSTMON Overvoltage Threshold	V _{BSTMON_OV}	V _{BSTMON} rising	0.92	0.95	0.98	V			
BSTMON Overvoltage Hysteresis	V _{BSTMON} OV HYS			50		mV			
BSTMON Input Bias Current	IBSTMON	0 < V _{BSTMON} < 1V	-1		+1	μA			
BSTMON Undervoltage- Trip Threshold	V _{OVPUVLO}	V _{BSTMON} rising	0.384	0.4	0.416	V			
Boost Undervoltage- Detection Delay	OVPUVLO_B LK			10		μs			
Boost Undervoltage-		After soft-start, fast_ss = 1	26.28	28.46	30.74	ma			
Blanking Time		After soft-startup, fast_ss = 0	49	53.25	57.5	1115			
TEMP PIN									
TEMP Pin Voltage	V _{TEMP}	I _{TEMP} = -10μA	380	400	420	mV			
TEMP to IOUT_ Gain				0.667		%/µA			
TEMP Pin Disable Threshold				0.5		V			

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Electrical Characteristics (continued)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS				
TEMP Pin Leakage Current		+25°C		0.05	1	μA				
TEMP Current for LED Current Disable	ITEMPD		80	120	160	μA				
PROGRAMMING VOLTAGE										
V _{PROG} Voltage			8.2	8.5	8.8	V				
V _{PROG} Voltage Undervoltage Threshold		V _{PROG} rising		8	8.2	V				
V _{PROG} Voltage Overvoltage Threshold		V _{PROG} falling	8.8	9		V				
V _{PROG} Input Current		During NV programming, T _A = +25°C		9	25	mA				
NV Programming Time				16	20	ms				
LOGIC INPUTS AND OU	TPUTS (EN, SCL	., SDA, DIM, ADD, MODE, PFO)								
Digital Inputs Logic-High	VIH		1.25			V				
Digital Inputs Logic-Low	V _{IL}				0.5	V				
Digital Inputs Hysteresis	V _{HYS}			300		mV				
EN Input Pull-down Resistor			100	165		kΩ				
EN Blanking Time	^t EN_BLK			10		μs				
DIM Pull-up Current	I _{DIM}	V _{DIM} = 0V		5		μA				
ADD and MODE Pull-up Current	IADD_MODE	V _{ADD} = V _{MODE} = 0V		2		μA				
SCL Input Current	I _{SCL}	V _{SCL} = +5V			+1	μA				
PFO, FLTB, SDA Output Low Voltage	V _{OL_OUT}	I _{FLTB} = I _{SDA} = I _{PFO} = 5mA			0.4	V				
PFO, FLTB, SDA Output Leakage Current	IOUT_LEAK	V _{EN} = 0V, V _{FLTB} = V _{SDA} = V _{PFO} = 5.5V			+1	μA				
THERMAL WARNING/SH	IUTDOWN									
Thermal-Warning Threshold, TFT Section	T _{WARN_TFT}	Temperature rising		125		°C				
Thermal-Warning Threshold, Backlight Section	T _{WARN_BL}			125		°C				
Thermal-Shutdown Threshold, TFT Section	T _{SHDN_TFT}	Temperature rising		165		°C				
Thermal-Shutdown Threshold, Backlight Section	T _{SHDN_BL}	Temperature rising		160		°C				
Thermal-Shutdown Hysteresis	T _{SHDN_HYS}			17		°C				
I ² C INTERFACE										
Clock Frequency	fSCL				0.4	MHz				

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Electrical Characteristics (continued)

 $(V_{IN} = 3.3V, V_{BATT} = 12V, typical operating circuit, T_A = T_J = -40^{\circ}C$ to +125°C, unless otherwise noted. Typical values are at T_A = +25°C. (*Note 1*))

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Hold Time (Repeated) START	^t HD:STA		600			ns
SCL Low Time	t _{LOW}		1300			ns
SCL High Time	tHIGH		600			ns
Setup Time (Repeated) START	^t SU:STA		600			ns
Data Hold Time	thd:dat		0			ns
Data Setup Time	t _{SU:DAT}		100			ns
Setup Time for STOP Condition	tsu:sto		600			ns
Spike Suppression				50		ns

Note 1: Limits are 100% tested at T_A = +25°C, T_A = +125°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.

Note 2: Guaranteed by design. Not production tested.

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Typical Operating Characteristics

 $(T_A = +25^{\circ}C, V_{IN} = V_{INN} = 3.3V, V_{BATT} = 12V, f_{DIM} = 200Hz$, unless otherwise noted.)

2.9







TOTAL IN QUIESCENT CURRENT

vs. TFT SUPPLY VOLTAGE





AVDD + NAVDD LINE REGULATION



AVDD LINE REGULATION AT 6.8V







AVDD LOAD REGULATION AT 6.8V





EFFICIENCY (%)

10%

0%

0



 $\mathbf{I}_{\text{AVDD}} = \mathbf{I}_{\text{NAVDD}} (\text{mA})$

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, V_{IN} = V_{INN} = 3.3V, V_{BATT} = 12V, f_{DIM} = 200Hz$, unless otherwise noted.)



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100ms/div

40ms/div

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Typical Operating Characteristics (continued)

(T_A = +25°C, V_{IN} = V_{INN} = 3.3V, V_{BATT} = 12V, f_{DIM} = 200Hz, unless otherwise noted.)





LED DRIVER EFFICIENCY



LED OPEN FAULT ON OUT1





2ms/div

f_{DIM} = 200Hz





LED DRIVER EFFICIENCY vs. I_{SET} CURRENT 100% f_{SW} = 400kHz L = 10µH 98% 96% 94% EFFICIENCY (%) 92% 90% 88% 86% f_{SW} = 2Μπ2 L = 4.7μH = 2MHz 84% 9 LEDS 82% V_{BATT} = 12V 80% 20 40 60 80 100 120 140 160 ISET CURRENT (mA)



OUT

OUT:

OUT

OUT

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, V_{IN} = V_{INN} = 3.3V, V_{BATT} = 12V, f_{DIM} = 200Hz$, unless otherwise noted.)





TEMPERATURE (°C)







4ms/div



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Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Pin Configuration

MAX25069



Pin Description

PIN	NAME	FUNCTION
1	IREF	Reference Current Set Pin. Connect a 1% resistor of value $22k\Omega$ from IREF to GND.
2	TEMP	Temperature Sensor Input. To implement LED current reduction at high temperatures, connect an NTC temperature sensor (e.g., the NTCLE100E3103G) to GND with resistors from the NTC to TEMP and to V18. If unused, connect TEMP to V18.
3	V _{PROG}	Programming Voltage. Apply a voltage of 8.5V to this pin during the programming of nonvolatile registers. Connect to GND through a resistor during normal operation.
4	V18	Output of Internal 1.8V Regulator. Connect 1μ F and $22n$ F capacitors in parallel from V18 to GND with an additional 100nF capacitor close to the V18 and GND pins.
5	GND	Ground Connection
6	IN	Supply Input. Connect at least one $10\mu F$ ceramic capacitor from IN to GND for proper operation.
7	INN	Buck-Boost Converter Input. Connect a $10\mu F$ ceramic capacitor from INN to GND for proper operation.
8	NAVDD	Negative Source-Driver Output Voltage
9	LXN	DC-DC Inverting Converter Inductor/Diode Connection
10	ADD	Device Address Select Pin. Connect to GND or V18 to select the device I^2C address. See <u>Table 5</u> . ADD has an internal pull-up to V18.

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Pin Description (continued)

PIN	NAME	FUNCTION				
11	MODE	Mode Selector Pin. Together with ADD, this pin determines the mode of operation of the I^2C interface and whether it is used. See <u>Table 3</u> . MODE has an internal pull-up to V18.				
12	VG _{OFF}	Output of Negative Charge-Pump Block. Connects directly to the negative charge-pump output to facilitate VG _{OFF} discharge through an internal switch connected between VG _{OFF} and GND. VG _{OFF} is also the regulator feedback pin.				
13	DN	Regulated Charge-Pump Driver for the Negative Charge Pump. Connect to an external flying capacitor.				
14	CPGND	Charge Pump Ground				
15	DP	Regulated Charge-Pump Driver for Positive Charge Pump. Connect to an external flying capacitor.				
16	PGVDD	Switched Version of HVINP Voltage for the Positive Charge Pump. Provides soft-start control of the VG _{ON} output. Bypass PGVDD with a 1μ F ceramic capacitor to GND.				
17	VG _{ON}	Output of Positive Charge-Pump Block. VG_{ON} connects directly to the positive charge-pump output to facilitate VG_{ON} discharge through an internal switch connected between VG_{ON} and GND. VG_{ON} is also the regulator feedback pin.				
18	AVDD	Positive Source-Driver Output Voltage. Bypass AVDD with a capacitor to GND.				
19	PGND1	Power-Ground Connection				
20	PGND2	Power-Ground Connection				
21	LXP1	Boost HVINP Converter Switching-Node Connection. Connect LXP1 to the external inductor and rectifier diode.				
22	LXP2	Boost HVINP Converter Switching-Node Connection. Connect LXP2 to the external inductor and rectifier diode.				
23	HVINP	Boost Output and Input for the AVDD, PGVDD, and Charge Pumps				
24	FLTB	Active-Low, Open-Drain Fault Indication Output. Connect an external pull-up resistor from FLTB to an external supply lower than 5V.				
25	EN	Enable Input. When EN is high, the device is enabled. With EN low, the device is in shutdown with low quiescent current. EN has an internal pull-down resistor.				
26	DIM	PWM Dimming Input. DIM has an internal pull-up to V18.				
27	SDA/ADIM	I ² C Data I/O. Connect a pull-up resistor from SDA to the system logic supply. In standalone mode, this pin is the analog dimming input (if unused, connect to GND).				
28	SCL	I ² C Clock Input. Connect a pull-up resistor from SCL to the system logic supply.				
29	PFO	Open-Drain Power-Fail Indicator Pin. When the IN voltage is below a threshold, the PFO output goes low. Add an external pull-up resistor between PFO and IN.				
30	NDRVS	Sense Connection for Gate of External MOSFET. Connect NDRVS directly to the gate after the gate resistor.				
31	NDRV	Switching nMOSFET Gate-Driver Output. Connect NDRV to the gate of the external switching- power MOSFET. Typically, a small resistor (1Ω to 22Ω) is inserted between the NDRV output and nMOSFET gate to decrease the slew rate of the gate driver and reduce the switching noise.				
32	V5	5V Regulator Output, Voltage Supply for NDRV Gate Driver. Place a 2.2µF ceramic capacitor as close as possible to V5 and PGND3.				
33	PGND3	Power-Ground Connection				
34	COMP	LED Driver Switching-Converter Compensation Input. Connect an RC network from COMP to GND to compensate the backlight boost converter (see the <i>Feedback Compensation</i> section).				
35	BSTMON	LED Driver Output-Voltage-Sensing Input. This voltage is used for overvoltage and undervoltage protection.				
36	CSN	LED Driver MOSFET Negative Current-Sense Connection. Connect this pin directly to the GND side of the compensation network connected to the COMP pin.				

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Pin Description (continued)

PIN	NAME	FUNCTION
37	CSP	LED Driver MOSFET Positive Current-Sense Connection. Connect a sense resistor from the MOSFET source to PGND and a further resistor from the MOSFET source to the CSP pin to set the slope compensation (see the <u>Current-Sense Resistor and Slope Compensation</u> section).
38	NGATE	Gate Connection for External Series nMOSFET Driven by the Internal Charge Pump
39	BATT	LED Driver Supply Input. Connect BATT to a 4.5V to 36V supply. Bypass BATT to ground with a ceramic capacitor.
40	OUT1	LED String 1 Cathode Connection
41	OUT2	LED String 2 Cathode Connection. Connect OUT2 to ground using a $9.1k\Omega$ resistor, if not used.
42	OUT3	LED String 3 Cathode Connection. Connect OUT3 to ground using a $9.1k\Omega$ resistor, if not used.
43	LGND	LED Ground Connection
44	OUT4	LED String 4 Cathode Connection. Connect OUT4 to ground using a $9.1k\Omega$ resistor, if not used.
45	OUT5	LED String 5 Cathode Connection. Connect OUT4 to ground using a $9.1k\Omega$ resistor, if not used.
46	OUT6	LED String 6 Cathode Connection. Connect OUT4 to ground using a $9.1k\Omega$ resistor, if not used.
47	N.C.	Not internally connected.
48	RT	Frequency Setting Resistor for Backlight Boost Converter
_	EP	Exposed Pad. Connect to a large contiguous copper-ground plane for optimal heat dissipation. Do not use EP as the only electrical ground connection.

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

Detailed Description

The MAX25069 is a highly integrated TFT power supply and LED backlight driver IC for automotive TFT-LCD applications. The IC integrates one boost converter, one inverting buck-boost converter, two gate-driver supplies, and a boost/SEPIC controller that can power 1 to 6 strings of LEDs in the display backlight. The complete device configuration can be stored in on-board nonvolatile memory.

The source-driver power supplies consist of a boost converter and an inverting buck-boost converter that can generate voltages up to +18V and down to -10.5V. The positive source-driver can deliver up to 300mA at 13.5V, while the negative source driver is capable of 200mA. The positive source-driver-supply regulation voltage (V_{AVDD}) is set through I²C. The negative source-driver-supply voltage (V_{NAVDD}) is always tightly regulated to - V_{AVDD} . The source-driver supplies operate from an input voltage between 2.65V and 5.5V.

The gate-driver-power supplies consist of regulated charge pumps that generate up to +31.5V and down to -18V and can deliver up to 15mA each.

The IC features a 6-string LED driver with input switch control (NGATE) that can power up to 6 strings of LEDs with 150mA (max) of current per string. Logic-controlled and I²C-controlled pulse-width modulation (PWM) dimming are included, with minimum pulse widths as low as 300ns and the option of phase shifting the LED strings with respect to one another. When phase shifting is enabled, each string is turned on at a different time, reducing the input and output ripple, as well as audible noise. With phase shifting disabled, each current sink turns on at the same time and allows parallel connection of current sinks.

The startup and shutdown sequences for all power domains are controlled using one of the eight preset modes that are selectable using a nonvolatile setting. When a regulator other than HVINP is enabled, the HVINP boost is automatically enabled (if not previously active). In this case, the second regulator is enabled when the soft-start of HVINP has completed.

Supply Voltages

The voltage on IN is the main supply voltage for the device. An on-chip regulator derives a 1.8V supply from the voltage on IN, and this 1.8V supply provides power to most of the on-chip circuitry. The IN voltage must be greater than V_{IN_UVLO} to allow device operation. In addition, V18 must be greater than V_{V18_UVLO} for the device to function. If the voltage on IN drops below V_{PFO} , the PFO output asserts low until the V18 supply reaches its undervoltage lockout level. When IN is connected directly to EN, a vin_uvlo fault may be detected at power-up. To avoid this, place a filter with a time constant of at least 10ms composed of a resistor from IN to EN and a capacitor from EN to GND.

The voltage on the BATT pin is the reference for the NGATE drive output. The voltage on BATT must exceed V_{BATT_UVR} in order for the backlight section to work. (V5 must also exceed V_{VCC_UVLOR} .) Once the backlight block is operating, the BATT voltage can drop as low as V_{BATT_UVF} while maintaining operation (and V5 must remain above V_{VCC_UVLOF} at all times). The drive output for the external boost MOSFET (NDRV) is powered from the V5 voltage, which is nominally 5V. V5 is derived from the HVINP voltage. In the case of HVINP voltages less than 5V, the V5 regulator will be in dropout and the NDRV output will not reach 5V.

PFO Output

PFO is an open-drain output which indicates that the voltage on the IN pin is below a threshold of V_{PFO_F}. The PFO output asserts low in this situation.

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias



Figure 1. PFO Waveform

The threshold for the PFO output can be selected using the pfo_th bit in the SEQ register (address 0x09). This bit can also be stored in nonvolatile memory. The nominal thresholds are shown in <u>Table 1</u>:

Table 1. PFO Thresholds

SETTING OF pfo_th BIT	PFO FALLING THRESHOLD (V)
0 (default)	2.5
1	2.4

TFT Power Section

Source-Driver Power Supplies

The source-driver power supplies consist of a boost converter (with output at HVINP) with output switch and an inverting buck-boost converter that can be used in one of two ways:

- Boost converter only or unipolar mode: In this case, the boost converter output voltage range is from 11.7V to 18V, the VG_{ON} range is from 12.6V to 31.5V, and the inverting converter is not used. To invoke this mode, set the dis_navdd bit in register TFT_CONFIG to 1. In this mode, the external components on LXN and NAVDD can be omitted and INN should be connected to IN.
- Bipolar mode: In this mode, both converters operate and the inverting converter output voltage tracks the output voltage of the boost converter. V_{NAVDD} cannot be adjusted independently of V_{AVDD}. In this mode, the boost converter output voltage range is 4.9V to 10.5V, and the VG_{ON} range is 8.4V to 21V. This is the default mode of operation (dis_navdd = 0).

AVDD Switch

To facilitate sequencing, the AVDD current-limited switch connects the output of the HVINP boost converter to the capacitor at AVDD. When the AVDD output is turned on, the current limit of the switch is increased in eight steps to its final value. The total time to reach the maximum current limit setting is half of the soft-start time as set by the tstart[1:0] field in the SEQ register. This avoids a sudden drop in HVINP voltage or a surge in input current from IN during AVDD start-up.

Gate-Driver Power Supplies

The positive gate-driver power supply (VG_{ON}) generates up to +31.5V (max) and the negative gate-driver power supply (VG_{OFF}) generates as low as -18V (min). Both can supply up to 15mA output current in tripler/doubling inverter configurations. The VG_{ON} and VG_{OFF} regulation voltages are set independently by writing to the vgon[5:0] and vgoff[5:0] fields in the VG_{ON} and VG_{OFF} registers. Note that the VG_{ON} voltage also depends on the setting of the dis_navdd bit in

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

the TFT_CONFIG register (address 0x07).

Sequencing

When the start bit in the START register is set to 1, the outputs are enabled in the sequence programmed in the seq_set bits. The start bit can be set to 1 and stored in the nv_start nonvolatile bit so that the device powers up automatically when the EN pin is taken high. The setting should be written before the sequence is executed and should not be changed during the turn-on or turn-off sequences. The sequence options are shown in <u>Table 2</u>:

Table 2. Sequencing

	SEQUENCE SET BITS			POWER-ON				POWER-OFF (REVERSE-ORDER OF POWER-ON)			
SEQUENCE NO.	seq_set2	seq_set1	seq_set0	1st	2nd after t1 ms	3rd after t2 ms	4th after t3 ms	1st	2nd after t3 ms	3rd after t2 ms	4th after t1 ms
1	0	0	0	AVDD	NAVDD	VG _{OFF}	VG _{ON}	VG _{ON}	VG _{OFF}	NAVDD	AVDD
2	0	0	1	AVDD	NAVDD	VG _{ON}	VG _{OFF}	VG _{OFF}	VG _{ON}	NAVDD	AVDD
3 (default)	0	1	0	NAVDD	AVDD	VG _{OFF}	VG _{ON}	VG _{ON}	VG _{OFF}	AVDD	NAVDD
4	0	1	1	NAVDD	AVDD	VG _{ON}	VG _{OFF}	VG _{OFF}	VG _{ON}	AVDD	NAVDD
5	1	0	0	NAVDD	VG _{OFF}	AVDD	VG _{ON}	VG _{ON}	AVDD	VG _{OFF}	NAVDD
6	1	0	1	VG _{OFF}	VG _{ON}	NAVDD	AVDD	AVDD	NAVDD	VG _{ON}	VG _{OFF}
7	1	1	0	AVDD/ NAVDD	VG _{OFF}	VG _{ON}	_	VG _{ON}	VG _{OFF}	AVDD/ NAVDD	_
8	1	1	1	AVDD/ NAVDD	VG _{ON}	VG _{OFF}	_	VG _{OFF}	VG _{ON}	AVDD/ NAVDD	

When dis_navdd is set to 1 and the NAVDD output is disabled, the NAVDD slot in <u>Table 2</u> remains without the output being turned on.

The times in <u>Table 2</u> are determined by the delayt1, delayt2, and delayt3 settings in the DELAY register (address 0x08). The fastest power-up is obtained by setting the delays to 0. After all of the TFT outputs have exceeded their power-good levels, the backlight block is turned on.

The output voltages are not monitored during off sequencing; each output is turned off in turn using the programmed delays, as seen in <u>Figure 2</u>. When the delays are set to 0, outputs are turned off in sequence with 1ms delays. A sequence can be stored in nonvolatile memory by writing to the burn_otp_reg register.

The V18 linear regulator is powered down 200ms after the power-down sequence is complete if power-down is performed using the EN pin. After this time, the device is in shutdown mode and can be restarted by setting the EN input high. If the outputs are turned off by taking the START bit low, the V18 regulator remains on.

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias



Figure 2. Output Sequencing

Description of the LED Driver

The IC also includes a high-efficiency, high-brightness LED driver that integrates all of the necessary features to implement a high-performance backlight driver to power LEDs in medium-to-large-sized displays for automotive and general applications. The IC provides load-dump voltage protection up to 40V in automotive applications and incorporates two major blocks: a DC-DC controller with peak current-mode control to implement a boost, or a SEPIC-type switched-mode power supply and a 6-channel LED driver with 23mA to 150mA constant-current-sink capability per channel.

The IC features constant-frequency, peak current-mode control with programmable slope compensation to control the duty cycle of the PWM controller. The DC-DC converter implemented using the controller generates the required supply voltage for the LED strings from a wide input-supply range. Connect LED strings from the DC-DC converter output to the 6-channel constant-current-sink drivers (OUT1–OUT6) to control the current through the LED strings. The LED current in all 6 LED strings is set by writing to the iset[6:0] field in the ISET register (address 0x0A).

The IC features adaptive voltage control that adjusts the converter output voltage depending on the forward voltage of the LED strings. This feature minimizes the voltage drop across the constant-current-sink drivers and reduces power dissipation in the device. The backlight boost and current sinks are enabled when the complete sequence of the TFT bias section is completed.

The IC provides a very wide (16,666:1) PWM dimming range at 200Hz dimming frequency (with a dimming pulse as narrow as 300ns). The internal dimming signal is derived from the DIM signal or from the phase-shift dimming logic. Phase shifting of the LED strings can be disabled by writing to the psen bit in the BL_CONFIG1 register (address 0x0B).

Other advanced features include detection and string disconnect for open-LED strings, partially or fully shorted strings, and unused strings. Overvoltage protection clamps the BSTMON voltage and thus the converter output voltage in the event of an open-LED condition.

The shorted-LED string threshold is programmable using the sldet[1:0] field in the BL_CONFIG2 register (address 0x0C).

The FLTB signal asserts low to indicate open-LED, shorted-LED, and overtemperature conditions if they are not masked.

Disable individual current-sink channels by connecting the corresponding OUT_ to LGND_ through a $9.1k\Omega$ resistor (starting with OUT6). In this case, FLTB will not indicate an open-LED condition for the disabled channel.

Undervoltage Lockout

The WLED section features two UVLOs that monitor the input voltage at BATT and the output of the internal LDO

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

regulator at V5. The backlight boost is active only when both BATT and V5 exceed their respective UVLO thresholds.

Low-Voltage Operation

After the boost soft-start is completed, the MAX25069 can continue to operate with BATT voltages as low as 3V.

At very low input voltages, the efficiency of the boost converter reduces and the input current can reach very high levels as a consequence. When the BATT voltage falls below V_{BATT_LVF} , the boost converter current limit is automatically increased to V_{CSP_LV} , and the switching frequency is reduced if it is greater than 1.35MHz. In this mode, if the standard current limit is exceeded on four consecutive cycles, a 100ms timer is started which returns the current limit to its original value when it expires. When the input voltage returns above V_{BATT_LVR} , operation at the normal switching frequency is resumed.

The external boost converter components must be selected for worst-case operation. An alternative is to reduce the output power at low input voltages.

If the voltage at BATT drops below the undervoltage lockout level (V_{BATT_UVF}) at any time, the boost converter is disabled.

Oscillator Frequency/External Synchronization

The internal oscillator frequency is programmable between 400kHz and 2.2MHz using a timing resistor (R_{RT}) connected from the RT pin to GND. Use the following equation to calculate the value of R_{RT} for the desired switching frequency (f_{SW}):

$$R_{\rm RT} = \frac{26400000}{f_{\rm SW}} - 0.32$$

where R_{RT} is in k Ω and f_{SW} is in Hz. If the value of the RT resistor is too low or if the pin is shorted to GND, the boost converter does not start, the FLTB pin goes low, and the rtoor bit in the BL_DIAG register is set.

To synchronize the oscillator with an external clock, AC-couple the external clock to the RT input. The value of the capacitor used for AC-coupling is C_{SYNC} = 10pF, and the duty cycle of the external clock should be 50%. When synchronizing the converter, do not apply the synchronizing signal to the RT pin at startup, as this may cause the RT resistor value check to fail.

At low input voltages and when the switching frequency is above 1.35MHz, the switching frequency is automatically reduced to 1.35MHz to enable high-duty-cycle operation and maintain output voltage regulation. This does not apply when the device is synchronized to an external frequency.

Spread-Spectrum Modulation

The IC includes a spread-spectrum mode that reduces peak electromagnetic interference (EMI) at the switching frequency and its harmonics. Spread spectrum can be enabled and disabled using the bl_ss_off bit in the BL_CONFIG2 register (address 0x0C).

Spread spectrum uses a pseudorandom dithering technique where the switching frequency is varied in the 94% to 106% or 97% to 103% range (set by the bl_ssl bit in BL_CONFIG2) of the programmed switching frequency set through the external resistor from RT to GND. When spread spectrum is used, the total energy at the fundamental and each harmonic is spread over a wider bandwidth, thus reducing the peak energy at the relevant frequency.

Spread spectrum is disabled if external synchronization is used.

LED Forward Voltage

The forward voltage of the LEDs driven by the MAX25069 varies with current and temperature. While the LED forward voltage increases with current, it decreases with temperature. The highest voltage across a string of LEDs is thus encountered at the minimum operating temperature. When using the MAX25069, the worst-case total string voltage (at the minimum operating temperature) including the voltage across the device OUT_ pins should be kept below the absolute maximum rating of 42V. Under normal operating conditions and over temperature, it is recommended that the boost output voltage be less than or equal to 36V. Select the BSTMON resistor-divider in order to guarantee a maximum voltage of 42V using the procedure described in the <u>Open-LED Management and Overvoltage Protection (OVP)</u> section.

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LED Current Control

The IC features 6 identical constant-current sources used to drive multiple high-brightness LED strings. The current through each of the channels is adjustable between 23mA and 150mA by setting the 7-bit value iset in the ISET register.

Multiple channels can be paralleled together for string currents exceeding 150mA.

Current-Mode DC-DC Controller

The IC backlight boost is a constant-frequency, current-mode controller designed to drive the LEDs in a boost or SEPIC configuration. The IC features multiloop control to regulate the peak current in the inductor, as well as the voltage across the LED current sinks to minimize power dissipation.

Programmable slope compensation is used to avoid subharmonic oscillation that can occur at > 50% duty cycles in continuous-conduction mode.

The external nMOSFET is turned on at the beginning of every switching cycle. The inductor current ramps up linearly until it is turned off at the peak current level set by the feedback loop. The peak inductor current is sensed from the voltage across the current-sense resistor (R_{CS}) that is connected from the source of the external nMOSFET to PGND.

The IC features leading-edge blanking to suppress the external nMOSFET switching noise. A PWM comparator compares the current-sense voltage plus the slope-compensation signal with the output of the transconductance error amplifier. The controller turns off the external nMOSFET when the voltage at CS exceeds the error amplifier's output voltage (at the COMP pin). This process repeats every switching cycle to achieve peak current-mode control.

In addition to the peak current-mode-control loop, the IC has two other feedback loops for control. The converter output voltage is sensed through the BSTMON input, which goes to the inverting input of the error amplifier.

The BSTMON gain (A_{OVP}) is defined as V_{OUT}/V_{BSTMON} , or (R17 + R16)/R16 (see the <u>Typical Application Circuit</u>). The other feedback comes from the OUT_ current sinks. This loop controls the headroom of the current sinks to minimize total power dissipation, while still ensuring accurate LED current matching. Each current sink has a window comparator with a low threshold of 0.58V and a high threshold of 0.85V. These comparators drive logic that controls an up/down counter. The up/down counter is updated on every falling edge of the DIM input and drives an 8-bit digital-to-analog converter (DAC), which sets the reference to the error amplifier. When the system is in steady state, all of the active OUT_ pin voltages should be over the minimum window threshold, and at least one should be lower than the upper threshold.

9-Bit Digital-to-Analog Converter (DAC)

The error amplifier's reference input is controlled with an 9-bit DAC. The DAC output is ramped up during startup to implement a soft-start function (see the <u>Startup Sequence</u> section). During normal operation, the DAC output range is limited to between 0.482V and 0.996V. Because the DAC output is limited to no less than 0.482V during normal operation, the overvoltage threshold for the output should be set to a value less than twice the minimum LED forward voltage. The DAC LSB determines the minimum output-voltage step according to the following equation:

$V_{\text{STEP}_{\text{MIN}}} = V_{\text{DAC}_{\text{LSB}}} \times A_{\text{OVP}}$

where V_{STEP_MIN} is the minimum output-voltage step, V_{DAC_LSB} is 1.95mV (typ), and A_{OVP} is the BSTMON resistordivider gain.

Startup Sequence

The WLED section startup sequence occurs in three stages, which are described in the following sections and illustrated in Figure 3. The overall startup time can be selected using the fast_ss bit in the BL_CONFIG1 register. The boost output voltage at the end of soft-start (the end of Stage 2) differs between the slow- and fast-startup modes.

Stage 1

After the TFT sequence has been completed, the controller turns on the charge-pump for the external nMOSFET if the V5 and BATT voltages are above their respective undervoltage thresholds. The output current of the charge-pump charges the gate of the external nMOSFET, thus turning it on. After a 2ms timeout, stage 2 of the startup begins. If NGATE is unused, set the cp_dis bit in the BL_DIS register (address 0x0D) to disable the NGATE charge pump.

Stage 2

After the external MOSFET on NGATE has been enabled, the IC goes through its power-up checks, including unused

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string detection, OUT_ short-to-ground detection, RT pin open/short detection, and IREF short detection. To avoid possible damage, the converter does not start if any OUT_ is detected as shorted to ground.

Any current sinks detected as unused are disabled to prevent a false fault-flag assertion during normal operation. After these checks have been performed, the converter begins to operate and the output voltage begins to ramp up. The DAC reference to the error amplifier is stepped upwards until the BSTMON pin reaches 0.48V (or 0.88V in fast-startup mode).

This stage duration is fixed at approximately 50ms (22ms in fast-startup mode).

Stage 3

The third stage begins once the second stage is complete and the DIM input goes high. During Stage 3, the output of the converter is adjusted until the minimum OUT_ voltage falls within the window comparator limits of 0.58V (typ) and 0.85V (typ). The output ramp is again controlled by the DAC, which provides the reference for the error amplifier. The DAC output is updated on each rising edge of the DIM input. If the DIM input is a 100% duty cycle (DIM = high), then the DAC output is updated once every 10ms.

The total soft-start time can be calculated using the following equation in slow-startup mode:

$$t_{\rm SS} = 50 \text{ms} + \frac{V_{\rm LED} + 0.875 - (0.48 \times A_{\rm OVP})}{f_{\rm DIM} \times 0.01 \times A_{\rm OVP}}$$

where t_{SS} is the total soft-start time, 50ms is the fixed Stage 1 duration, V_{LED} is the total forward voltage of the LED strings, 0.715V is midpoint of the window comparator, A_{OVP} is the gain of the OVP resistor-divider, f_{DIM} is the dimming frequency (use 100Hz if the DIM input duty cycle is 100%), and 0.01V is the maximum voltage step per clock cycle of the DAC.

In fast-startup mode (with the fast_ss bit in the BL_CONFIG1 (0x0B) register set to 1), the following equation should be used:

 $t_{\rm SS} = 22\text{ms} + \frac{0.88 \times A_{\rm OVP} - (V_{\rm LED} + 0.875)}{f_{\rm DIM} \times 0.01 \times A_{\rm OVP}}$

Backlight Boost Startup



Figure 3. Backlight Boost Startup

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Open-LED Management and Overvoltage Protection (OVP)

On power-up, the IC detects and disconnects any unused current-sink channels before entering the DC-DC converter soft-start. This avoids asserting the FLTB output for the unused channels. After soft-start, the IC detects open strings and disconnects them from the internal minimum OUT_ voltage detector. This keeps the DC-DC converter output voltage within safe limits and maintains high efficiency.

If any LED string is open, the voltage at the open OUT_ goes to GND. The DC-DC converter output voltage then increases to the overvoltage-protection threshold set by the voltage-divider network connected between the converter output, BSTMON input, and GND (the threshold at which the PWM controller is switched off, holding NDRV low). At that point, any current-sink output with V_{OUT} < 250mV (typ) is disconnected from the minimum-voltage detector. Select V_{OUT} over (which is the maximum voltage that the boost converter can produce) according to the following equation:

$$V_{\text{OUT OVP}} > 1.1 \times (V_{\text{LED MAX}} + 1)$$

where V_{LED_MAX} is the maximum expected LED string voltage. V_{OUT_OVP} should also be chosen such that the voltage at the OUT_pins does not exceed the absolute maximum rating.

The upper resistor in the BSTMON resistor-divider (R17) can be selected using the following equation:

$$R17 = R16 \times (\frac{V_{OUT}_{OVP}}{0.95} - 1)$$

where 0.95V is the typical BSTMON threshold. Ensure that the minimum voltage on the BSTMON pin is always greater than 0.4V to avoid the boost converter latching off due to undervoltage by checking the following:

$$(V_{\text{LED}_{\text{MIN}}} + 0.55) \times \frac{R16}{R16 + R17} > 0.4V$$

where V_{LED} MIN is the worst-case minimum LED string voltage.

When an open-LED condition occurs, FLTB is asserted low, and the bit corresponding to the channel with the fault is set to 1.

If the boost voltage reaches the BSTMON overvoltage threshold without any open channels, the converter is immediately disabled until the BSTMON voltage drops by 50mV, upon which switching resumes. In this condition, the boost converter output voltage is triangular due to the hysteretic mode of operation, and the bstov bit in the BL_DIAG register is set.

Short-LED Detection

The IC checks for shorted LEDs at the falling edge of OUT_. An LED short is detected at OUT_ if the OUT_ voltage is greater than the value programmed using the sldet[1:0] field in the BL_CONFIG2 register. Once a short is detected on any of the strings, the LED strings with the short are disconnected and the FLTB output flag asserts (unless the fault is masked) until the device detects that the shorts are removed on any of the following rising edges of DIM. Short-LED detection is disabled in low-dimming mode. If the DIM input is connected high, short-LED detection is performed continuously.

Short-LED detection is also disabled in cases where all active OUT_ channels rise above the threshold set by the SLDET[1:0] bits in register BL_CONFIG2 (address 0x0C). This can occur in a boost-converter application when the input voltage becomes higher than the total LED string voltage drop, such as during a battery load dump. If a short-LED fault occurs during a load dump, the fault flag does not assert until the load dump is over and the minimum OUT_ voltage has fallen below 2.028V. If a load dump occurs after a short LED is detected, the fault flag deasserts until the load dump is over and the minimum OUT_ voltage has fallen below 2.028V, at which point the fault flag reasserts.

Dimming

Dimming can be performed using an external PWM signal applied to the DIM pin or by writing to the TON_registers. The signal on the DIM pin is sampled with a 20MHz internal clock except when phase-shifting is disabled, in which case the DIM signal controls the OUT_ outputs directly.

Low-Dimming Mode

The IC's operation changes at very narrow dimming pulses to ensure a consistent dimming response of the LEDs. If the dimming on-time is lower than $50\mu s$ (typ), the device enters low-dimming mode. In this state, the converter switches continuously and LED short detection is disabled. When the DIM input is greater than $51\mu s$ (typ), the device goes back

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into normal operation, enabling the short-LED detection and switching the power FET only when the effective dimming signal is high.

Phase-Shift Dimming

When the psen bit in register BL_CONFIG1 (address 0x0B) is set, phase shifting of the LED strings is enabled. To achieve this, the DIM signal is sampled internally by a 20MHz clock. The device automatically sets the phase shift between strings to a value depending on the number of strings enabled.

When phase shifting is enabled, the sampled DIM input is used to generate separate dimming signals for each LED string that is shifted in phase. The resolution with which the DIM signal is captured degrades at higher DIM input frequencies; therefore, dimming frequencies between 100Hz and 3kHz are recommended, although higher dimming frequencies are technically possible. The phase shift between strings is determined by the following equation:

Θ = 360 n

where n is the total number of strings being used and θ is the phase shift in degrees. See <u>Figure 4</u> for a timing diagram example with phase shifting enabled.

When phase shifting is disabled, all strings turn on/off at the same time. If multiple current sinks are being connected in parallel, phase shifting should be disabled.

If a fault is detected, resulting in a string being disabled during normal operation, the phase shifting adjusts to the new situation.

When disabling unused strings, disable the higher-numbered OUT_ current sinks first.



Figure 4. Phase-Shifted Outputs

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Automatic Fade-In/Fade-Out During Dimming

The device can be configured to perform a smooth change in brightness, even when the DIM input duty cycle or TON_ setting is suddenly changed by setting the FADE_IN_OUT bit in the BL_FADING register to 1.

When using the fade function, it is important to maintain the DIM frequency constant while entering and leaving 100% duty cycle. This is necessary in order to avoid erroneous frequency measurement that can change the speed of the fade-in/out.

The step size in the dimming transition is either 6.25% or 12.5%, depending on the setting of the FADE_GAIN bit. The total transition time can be set by writing the TDIM field to a value between 0 to 5, where the value sets the update speed to once every 2^{TDIM}. The transition time depends on the initial and final dimming values according to:

$$t = \frac{1}{f_{\text{DIM}}} \times 2^{\text{TDIM}} \times \frac{\ln(\text{DIM}_F) - \ln(\text{DIM}_j)}{\text{FADE}_{\text{GAIN}}}$$

where f_{DIM} is the dimming frequency, TDIM is the TDIM register setting, DIM_F is the final dimming setting, DIM_i is the initial dimming setting, and FADE_GAIN is either 0.0625 or 0.125. For this equation, DIM_F should be larger than DIM_i but, since the fading function is symmetrical, the values can be swapped if the final dimming ratio is lower than the initial one.

When transitioning to 100% dimming with fading enabled, do not change the input dimming from 100% until the complete fading transition to 100% is complete.

If fade-in is enabled at startup, the device will transition smoothly to the desired dimming level from 0. When the start bit is taken low or the EN pin set to ground, fade-out is not performed.

Disabling Individual Strings

To disable an unused LED string, connect the unused OUT_ to ground through a $9.1k\Omega$ resistor, or set the corresponding DIS_ bit to 1 in the BL_DIS register (address 0x0D) before the start bit is set. During backlight boost startup, the device sources 60μ A (typ) current through the OUT_ pins and measures the corresponding voltage. For the string to be properly disabled, the OUT_ voltage should measure between 270mV and 775mV during this check. The maximum threshold for the OUT_ short-to-ground check is 270mV, and the minimum unused string-detection threshold is 775mV.

Note: When disabling unused strings, start by disabling the highest numbered current sinks first (e.g., if two strings need to be disabled, disable OUT6 and the next channel down. Do not disable any two strings at random). During normal operation, strings can be selectively turned off by changing the corresponding TON_ setting to 0. This is only possible when internal dimming is used (not when using the DIM input pin).

Hybrid Dimming

To enable hybrid dimming, set the hdim bit in register BL_CONFIG1 (address 0x0B). With hybrid dimming enabled, the ADIM pin has no effect on device operation. In hybrid dimming mode, the external LEDs are dimmed by first reducing their current as the dimming duty-cycle decreases from 100% (see Figure 5). At the crossover level set by the hdim_thr[1:0] bits, dimming transitions to PWM dimming where the LED current is chopped. Depending on the dim_ext bit, the device functions in one of two ways:

- (dim_ext = 1) measures the duty cycle on the DIM pin and translates it into a combined LED current value and PWM setting.
- (dim_ext = 0) takes the 18-bit value from the TON1 register and translates it into a combined LED current value and PWM setting.

Figure 6 illustrates the difference between standard and hybrid dimming with phase-shifting enabled.

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Figure 5. Hybrid Dimming Operation with hdim_thr[1:0] = 10 (25%)



Figure 6. Hybrid Dimming Operation Modes

Temperature Foldback

When an NTC temperature sensor is connected between GND and a resistor (RT1) connected to the V18 supply, with a further resistor (RT2) connected from the junction of the NTC and RT1 to the TEMP pin, temperature foldback is implemented. When the temperature reaches the temperature T1 (set by RT1), the current in the LEDs is reduced according to the linear scheme shown in Figure 7. The slope of the current reduction is set by RT2. The MAX25069 is

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specifically designed to be used with the NTCLE100E3103G or a similar NTC device. Table 3 illustrates some examples of RT1 and RT2 values to obtain certain values of T1 and T_{DELTA} .

Table 3. Temperature Foldback Examples

RT1 (kΩ)	RT2 (kΩ)	T1 (°C)	T _{DELTA} (°C)
6.04	1.2	70	30
6.04	2	70	50

When the temperature reaches T1, the OTW bit in register DIAG_REG is asserted. When the temperature reaches T_{OFF}, the LED current is turned off, the bl_ot bit is set high, and the FLTB pin asserts low.



Figure 7. Temperature Foldback Curve

Fault Protection

The IC has robust fault and overload protection. If any of the VGOFF, NAVDD, AVDD, or VGON outputs fall to less than 85% (typ) of their intended regulation voltage for more than 15ms (typ), or if a short-circuit condition occurs on any output for any duration, then all outputs latch off and a fault condition is set. The backlight section also includes comprehensive diagnostics and fault signalling.

Both device sections (TFT and backlight) have independent thermal-fault detection and thermal warnings; only the section causing the thermal overload is turned off.

Thermal faults are cleared when the die temperature drops by 17°C.

When a fault is detected, the open-drain FLTB output goes low unless the fault is masked. The FLTB output pin is an active-low, open-drain output that can be used to signal various device faults The FLTB output can flag any or all of the conditions listed below.

In the TFT section:

- Undervoltage fault on HVINP, AVDD, NAVDD, VGON, or VGOFF
- Thermal warning in the TFT bias section
- Thermal shutdown in the TFT bias section

In the backlight section:

• Open fault on any of the OUT_ pins

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- Shorted-LED fault on any of the OUT_ pins
- Any OUT_ shorted to GND
- LED boost converter undervoltage
- IREF resistor out of range
- RT resistor out of range
- NTC fault
- Undervoltage on BATT
- Thermal warning in the backlight section
- Thermal shutdown in the backlight section
- In addition the following general faults are signalled:
- I²C parity error
- Undervoltage on the IN pin
- Nonvolatile memory fault

Some of the above conditions can be masked from causing FLTB to go low by using the corresponding mask bit in the TFTMASK1, TFTMASK2, and BL_MASK registers.

In standalone mode, if the fltb_mode bit is 0, the duty-cycle on the FLTB pin indicates the type of fault according to the following scheme:

- FLTB continuously low: Thermal-shutdown fault on either block, undervoltage on IN, or nonvolatile memory fault
- 25% duty cycle on FLTB: Faults in both LED and TFT sections
- 50% duty cycle on FLTB: Fault in TFT section
- 75% duty cycle on FLTB: Fault in LED section

This list is in order of priority where FLTB continuously low takes highest precedence.

Otherwise, if fltb_mode is 1, FLTB asserts low upon the occurrence of any fault.

Serial Interface

The MAX25069 IC features an I^2 C, 2-wire serial interface consisting of a serial-data line (SDA) and a serial-clock line (SCL). SDA and SCL facilitate communication between the IC and the controller at clock rates up to 400kHz. The controller, typically a microcontroller, generates SCL and initiates data transfer on the bus. The operation mode of the device is controlled by the ADD and MODE pins as shown in <u>Table 4</u>.

Table 4. Add/Mode Pins

MODE	ADD	OPERATION MODE	FLTB
GND	GND	Full I ² C read/write access	Low with fault
GND	V18	Full I ² C read/write access	Low with fault
V18	GND	Standalone mode, no I ² C access	PWM output with fault
V18	V18	I ² C read-only access	Low with fault

If the device powers up in standalone mode, it is latched in that mode, and the mode of operation can only be changed by powering off the device.

The read and write addresses are shown in <u>Table 5</u>.

Table 5. I²C Address

ADD PIN		DEVICE ADDRESS						WRITE	READ	
CONNECTION	A6	A5	A4	A3	A2	A1	A0	ADDRESS	ADDRESS	
GND	1	0	0	1	1	1	0	0x9C	0x9D	
V18	1	0	0	1	1	1	1	0x9E	0x9F	

A controller device communicates with the MAX25069 by transmitting the correct peripheral ID followed by the register address and data word. Each transmit sequence is framed by a START (S) or Repeated START (Sr) condition, and a STOP (P) condition. Each word transmitted over the bus is 8 bits long and is always followed by an acknowledge clock
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pulse.

The IC's SDA line operates as both an input and an open-drain output. A pull-up resistor greater than 500Ω is required on the SDA bus. In general, the resistor has to be selected as a function of bus capacitance such that the rise time on the bus is not greater than 120ns. The IC's SCL line operates as an input only. A pull-up resistor greater than 500Ω is required on SCL if there are multiple controllers on the bus, or if the controller in a single-controller system has an open-drain SCL output. In general, for the SCL-line resistor selection, the same SDA recommendations apply. Series resistors in line with SDA and SCL are optional. The SCL and SDA inputs suppress noise spikes to assure proper device operation, even on a noisy bus.

Nonvolatile (NV) Memory

The MAX25069 includes six blocks of one-time-programmable memory (the number of writes performed so far can be read from nv_count[2:0] in the REG_CTRL register). The user can store the block of volatile registers from 0x07 to 0x15 in nonvolatile memory, which is in turn mapped to register locations 0x17 to 0x25. Note that before the nonvolatile memory has been written to the first time, a read from the locations 0x17 to 0x25 yields the result 0xFF.

The contents of the nonvolatile memory are protected by a single-error correction/double-error detection (SECDED) redundant code, while data transfer from nonvolatile memory to registers 0x07 to 0x15 is protected by a parity check. If the parity check fails, a retry is performed two times. If all three attempts are unsuccessful, the device does not start up, the nv_flt bit is set, and the FLTB pin is asserted low. If the SECDED check fails, the device does not start up, the nv_flt bit is set, and the FLTB pin is asserted low.

If there are no errors, the outputs are turned on with the stored values and in the stored sequence.

To store the contents of registers 0x07 to 0x15 to nonvolatile memory a voltage source of 8.5V $\pm 2\%$ capable of supplying more than 25mA should be connected to the V_{PROG} pin. When the V_{PROG} voltage is stable, an I²C NV write command can be performed by writing to the burn_otp_reg register. If the NV write is unsuccessful (because the V_{PROG} voltage was out of range or because of a general memory error), the nv_flt bit is set and the FLTB pin goes low. After an NV write command is executed, the nv_flt bit should be checked. If nv_flt is high, another NV write can be attempted.

Connect V_{PROG} to GND if there is no need to program the nonvolatile memory.

Autorefresh Function

When the refresh bit in register CONFIG is set, the device reads from the nonvolatile registers at intervals of 1s and writes the data into the corresponding volatile registers. This avoids the effect of possible corruption of the volatile registers. Autorefresh reads are subject to error correction in the same way as the initial read after device power-up.

See the <u>Using the NV Memory</u> section when programming the nonvolatile memory.

BURN, REBOOT, and RESTART Commands

The BURN and REBOOT commands are used to store the contents of registers 0x07 to 0x15 in nonvolatile memory or to fetch the contents of nonvolatile memory and load them into registers 0x07 to 0x15, respectively. The RESTART command is used to restart the device from a latched-fault mode. When a RESTART command is performed, all fault bits are cleared.

A BURN command is performed by writing 0xA5 to register address 0x78 (burn_otp_reg).

A REBOOT command is performed by writing 0x5A to register address 0x79 (reboot_otp_reg).

A RESTART command is performed by writing 0xC3 to register address 0x7A (soft_restart).

When parity checking is enabled and one of these user commands is sent to the device, the third byte should be such as to have even parity over the 3 bytes sent.

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Register Map

MAX25069

ADDRESS	NAME	MSB							LSB
USER REG	STERS								
0x00	DEVICE[7:0]	_	_			dev_i	d[5:0]		
0x02	REG_CTRL[7:0]	_	dis_refr	r	v_count[2:0)]		rev_id[2:0]	
0x03	TFTMASK1[7:0]	-	avdd_uv _mask	-	navdd_u v_mask	-	vgon_uv _mask	-	vgoff_uv _mask
0x04	TFTMASK2[7:0]	-	par_err_ mask	vin_uvlo _mask	hvinp_uv _mask	-	-	-	th_warn_ mask
0x05	TFT_FAULT1[7:0]	-	avdd_uv	-	navdd_u v	-	vgon_uv	-	vgoff_uv
0x06	TFT_FAULT2[7:0]	-	par_err	vin_uvlo	hvinp_uv	th_shdn	nv_flt	clk_err	th_warn
0x07	TFT_CONFIG[7:0]	dis_navd d	refresh	en_ss	fSW	tretry	/[1:0]	tfaul	t[1:0]
0x08	DELAY[7:0]	delay	t1[1:0]	delay	t2[1:0]	delay	t3[1:0]	-	par_en
0x09	<u>SEQ[7:0]</u>		seq_set[2:0]]	pfo_th	tstar	t[1:0]	lxp_lim_l ow	start
0x0A	ISET[7:0]	_				iset[6:0]		1	
0x0B	BL_CONFIG1[7:0]	dim_ext	hdim	hdim_	thr[1:0]	bstforce fast_ss		psen	fltb_mod e
0x0C	BL_CONFIG2[7:0]	bl_ilim		fpwm[2:0]		bl_ss_off	bl_ssl	slde	[1:0]
0x0D	BL_DIS[7:0]	cp_dis	_	dis_bl dis6		dis5	dis4	dis3	dis2
0x0E	BL_FADING[7:0]	-	-	-	fade_gai n	fade_in_ out		tfade[2:0]	-
0x0F	CUSTOMER_USE1[7:0]			1	customer	_use1[7:0]	1		
0x10	CUSTOMER_USE2[7:0]			customer_use2[7:0]					
0x11	CUSTOMER_USE3[7:0]			customer_use3[7:0]					
0x12	CUSTOMER_USE4[7:0]			customer_use4[7:0]					
0x13	AVDD_SET[7:0]	-	-			avdo	l[5:0]		
0x14	<u>VGON[7:0]</u>	_	_			vgor	n[5:0]		
0x15	VGOFF[7:0]	_	_			vgof	f[5:0]		
0x17	NV_CONFIG[7:0]	nv_dis_n avdd	nv_refres h	nv_en_s s	nv_fSW	nv_tre	try[1:0]	nv_tfa	ult[1:0]
0x18	NV_DELAY[7:0]	nv_dela	ayt1[1:0]	nv_dela	ayt2[1:0]	nv_dela	vyt3[1:0]	unused	nv_par_e n
0x19	NV_SEQ[7:0]	nv	/_seq_set[2	:0]	nv_pfo_t h	nv_tst	art[1:0]	nv_lxp_li m_low	nv_start
0x1A	<u>NV_ISET[7:0]</u>	unused			I	nv_iset[6:0]		I	1
0x1B	NV_BL_CONFIG1[7:0]	nv_dim_ ext	nv_hdim	nv_hdim	_thr[1:0]	nv_bstfor ce	nv_fast_ ss	nv_psen	nv_fltb_ mode
0x1C	NV_BL_CONFIG2[7:0]	nv_bl_ili m	r	nv_fpwm[2:0]		nv_bl_ss _off	nv_bl_ssl	nv_sld	let[1:0]
0x1D	NV_BL_DIS[7:0]	nv_cp_di s	unused	nv_dis_b I	nv_dis6	nv_dis5	nv_dis4	nv_dis3	nv_dis2

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ADDRESS	NAME	MSB							LSB
0x1E	NV_BL_FADING[7:0]		unused[2:0]		nv_fade_ gain	nv_fade_ in_out	r	v_tfade[2:0]
0x1F	NV_CUSTOMER_USE1 [7:0]		nv_customer_use1[7:0]						
0x20	NV_CUSTOMER_USE2 [7:0]		nv_customer_use2[7:0]						
0x21	NV_CUSTOMER_USE3				nv_custome	er_use3[7:0]			
0x22	NV_CUSTOMER_USE4				nv_custome	er_use4[7:0]			
0x23	NV_AVDD_SET[7:0]	unuse	ed[1:0]			nv_avo	dd[5:0]		
0x24	<u>NV_VGON[7:0]</u>	unuse	ed[1:0]			nv_vg	on[5:0]		
0x25	NV_VGOFF[7:0]	unuse	ed[1:0]			nv_vg	off[5:0]		
0x26	AVDD_LIM[7:0]	-	-			avdd_l	im[5:0]		
0x27	LO_DIM[7:0]	ton_mast er	-	lo_dim6	lo_dim5	lo_dim4	lo_dim3	lo_dim2	lo_dim1
0x28	TON1H[7:0]				ton1l	n[7:0]			
0x29	TON1L[7:0]		ton1l[7:0]						
0x2A	TON2H[7:0]		ton2h[7:0]						
0x2B	TON2L[7:0]	ton2l[7:0]							
0x2C	TON3H[7:0]		ton3h[7:0]						
0x2D	TON3L[7:0]				ton3	l[7:0]			
0x2E	TON1_3LSB[7:0]	-	-	ton3ls	b[1:0]	ton2ls	b[1:0]	ton1ls	b[1:0]
0x2F	TON4H[7:0]				ton4l	n[7:0]			
0x30	TON4L[7:0]				ton4	I[7:0]			
0x31	<u>TON5H[7:0]</u>				ton5l	ו[7:0]			
0x32	TON5L[7:0]				ton5	I[7:0]			
0x33	<u>TON6H[7:0]</u>				ton6l	ו[7:0]			
0x34	TON6L[7:0]				ton6	I [7:0]			
0x35	TON4_6LSB[7:0]	_	-	ton6ls	b[1:0]	ton5ls	b[1:0]	ton4ls	b[1:0]
0x36	OPEN_REG[7:0]	_	-	out6o	out5o	out4o	out3o	out2o	out1o
0x37	SHORTGND_REG[7:0]	_	_	out6sg	out5sg	out4sg	out3sg	out2sg	out1sg
0x38	SHORTED_LED_REG[7:0]	_	_	out6sl	out5sl	out4sl	out3sl	out2sl	out1sl
0x39	BL_MASK[7:0]	– battuv		battuvma sk	bstuvma sk	omask	sgmask	bl_otwm ask	slmask
0x3A	BL_DIAG[7:0]	_	rtoor	irefoor	bstuv	bstov	hw_rst	bl_otw	bl_ot
USER COM	MANDS								
0x78	burn_otp_reg[7:0]				burn_c	otp[7:0]			
0x79	reboot_otp_reg[7:0]				reboot_	otp[7:0]			
0x7A	soft_restart[7:0]				soft_res	start[7:0]			

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Register Details

DEVICE (0x00)

BIT	7	6	5	4	3	2	1	0
Field	-	-	dev_id[5:0]					
Reset	-	-						
Access Type	_	_	Read Only					
BITFIEI	LD	BITS	DESCRIPTION					
dev_id		5:0	Device ID, reads 0x29.					

REG_CTRL (0x02)

BIT	7	6	5	4		3	2	1	0	
Field	-	dis_refr	nv_count[2:0]				rev_id[2:0]			
Reset	_	0b0						0x0		
Access Type	_	Write, Read	Read Only				Read Only			
BITFIELD	BITS		DESCRIPT	ION		DECODE				
dis_refr	6	Refresh disa disable refre	Refresh disable bit. Use this bit to temporarily disable refresh before a burn_otp command.				fresh bit detern fresh disabled	nines whether r	efresh is on	
nv_count	5:3	This field inc to nonvolatil is 6.	This field indicates the total number of writes to nonvolatile memory. The maximum value is 6.							
rev_id	2:0	Revision ID.	Revision ID. Reads 0x0.							

TFTMASK1 (0x03)

BIT	7	6	5		4	3	2	1	0	
Field	_	avdd_uv_m ask	-		navdd_uv_ mask	-	vgon_uv_m ask	_	vgoff_uv_m ask	
Reset	-	0x0	-		0x0	-	0x0	-	0x0	
Access Type	_	Write, Read	Read –		Write, Read	-	Write, Read	-	Write, Read	
BITFIEI	BITFIELD BITS					DE	SCRIPTION			
avdd_uv_mask	ζ.	6		When 1, this bit prevents an undervoltage on AVDD from asserting FLTB lo						
navdd_uv_mas	šk	4	4		When 1, this bit prevents an undervoltage on NAVDD from asserting low.				ting FLTB	
vgon_uv_mask	on_uv_mask 2			Wher	1, this bit prev	ents an under	voltage on VG	_{DN} from asserti	ng FLTB low.	
vgoff_uv_mask	(0		When 1, this bit prevents an undervoltage on VG _{OFF} from asserting FLTB low.						

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TFTMASK2 (0x04)

BIT	7	6	5	;	4	3	2	1	0	
Field	_	par_err_ma sk	vin_uv as	/lo_m ⊧k	hvinp_uv_m ask	-	_	-	th_warn_ma sk	
Reset	-	0x0	0x	:0	0x0	-	-	-	0x1	
Access Type	_	Write, Read	Write,	Read	Write, Read	-	_	-	Write, Read	
BITFIEI	BITFIELD BITS					DE	SCRIPTION			
par_err_mask		6		When 1, prevents parity errors from asserting the FLTB pin.						
vin_uvlo_mask		5		Wher	n 1, this bit prev	ents an under	voltage on IN fi	rom asserting t	ne FLTB pin.	
hvinp_uv_mas	k	4		Mask not ca	Mask bit for hvinp_uv diagnostic. When 1, an undervoltage on HVINP does not cause FLTB to assert.					
th_warn_mask		0		Wher low.	When 1, this bit prevents an overtemperature warning from asserting FLTB low.					

TFT_FAULT1 (0x05)

BIT	7	6	5		4	3	2	1	0
Field	-	avdd_uv	_		navdd_uv	-	vgon_uv	-	vgoff_uv
Reset	-	0x0	-		0x0	-	0x0	-	0x0
Access Type	_	Read Clears All	_		Read Clears All	_	Read Clears All	_	Read Clears All
BITFIEI	BITFIELD BITS			DESCRIPTION					
avdd_uv		6		Wher	1, this bit indic	cates an under	voltage on AVI	DD.	
navdd_uv	4			When 1, this bit indicates an undervoltage on NAVDD.					
vgon_uv	gon_uv 2			Wher	1, this bit indic	cates an under	voltage on VG	-NC	
vgoff_uv		0		When 1, this bit indicates an undervoltage on VG _{OFF} .					

TFT_FAULT2 (0x06)

BIT	7	6	5		4	3	2	1	0			
Field	-	par_err	vin_u	olvi	hvinp_uv	th_shdn	nv_flt	clk_err	th_warn			
Reset	-	0x0	0x(0	0x0	0x0	0x0	0x0	0x0			
Access Type	_	Read Clears All	Rea Clears	ad s All	Read Clears All	Read Clears All	Read Clears All	Read Only	Read Clears All			
BITFIELD BITS					DESCRIPTION							
par_err		6	Indicates that a parity error was detected on an I ² C transaction.									
vin_uvlo	vlo 5			Indica devic after	ates an undervo e turns off all or which the outpu	oltage conditior utputs and wait uts are reenable	n on the IN pin. ts for IN to retu ed in the progra	When this hap rn above the IN ammed sequer	pens, the I UVLO level, nce.			
hvinp_uv		4		Wher	n 1, this bit indic	cates an under	voltage on the	boost output, ⊦	IVINP.			
th_shdn	shdn 3			Wher and t	n 1, this bit indic nat the complet	cates an overte e device has b	mperature shu een turned off.	tdown on the T	FT section			
nv_flt		2		Nonvolatile memory failure – unsuccessful transfer of the contents of NV memory to working memory or more than one error detected.								

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BITFIELD	BITS	DESCRIPTION
clk_err	1	When this bit is 1, the clock for either the TFT or the backlight section has been inactive for 5µs or is out of range. Unless this fault is masked, the FLTB pin asserts low and the local microcontroller should disable the device using the EN pin. This fault can only be cleared by power-on reset (POR).
th_warn	0	When 1, this bit indicates a thermal warning.

TFT_CONFIG (0x07)

BIT	7	6	5	4		3	2	1	0
Field	dis_navdd	refresh	en_ss	fSW		tretry	/[1:0]	tfault	[1:0]
Reset	0x0	0x0	0x0	0x0		0x1 0x0			:0
Access Type	Write, Read	Write, Read	Write, Read Write, Read Write, Read				Read	Write,	Read
BITFIELD	BITS		DESCRIPT	ION			D	ECODE	
dis_navdd	7	When set to converter. S device using should not b operation.	1, this bit disal et this bit befor g the start bit. T e changed dur	bles the NAVDI re enabling the 'he dis_navdd b ing device	D Dit				
refresh	6	When this b registers are volatile regis	it is 1, the conte automatically sters every sec	ents of the NV copied to the ond.		0x0: Re 0x1: Re	fresh disabled fresh enabled		
en_ss	5	Enable spre 1.	ad-spectrum by	y setting this bi	t to				
fSW	4	Sets switchi	ng frequency o	f TFT section.		0x0: 2.1MHz 0x1: 420kHz			
tretry	3:2	Sets retry tir	ne after a fault.			0x0: Re 0x1: Re 0x2: Re 0x3: Re	try disabled try after 0.95s, try after 1.9s, to try after 1.9s	total 3 retries otal 3 retries	
tfault	1:0	Sets fault de	elay time.			0x0: 15r 0x1: 30r 0x2: 60r 0x3: 90r	ns ns ns ns		

DELAY (0x08)

BIT	7	6	5	5 4		2	1	0				
Field	del	ayt1[1:0]	delay	rt2[1:0]	delayt3[1:0]		-	par_en				
Reset		0x2	0	x2	0x2		-	0x0				
Access Type	Wri	te, Read	Write	, Read	Write,	Read	-	Write, Read				
BITFIEI	BITFIELD BITS			DESCRIPTION								
delayt1		7:6	Set d 15ms	Set delay t1 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.								
delayt2	5:4		Set d 15ms	Set delay t2 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.								
delayt3 3:2		Set d 15ms	Set delay t3 in the start-up sequence. Choose between 0, 5ms, 10ms, and 15ms.									

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BITFIELD	BITS	DESCRIPTION
par_en	0	Parity enable bit. When 1, this bit enables parity checking on write transactions to the device.

<u>SEQ (0x09)</u>

BIT	7	6	5	4		3	2	1	0	
Field		seq_set[2:0]		pfo_th		tstar	t[1:0]	lxp_lim_low	start	
Reset		0x2		0x0		0:	x1	0b0	0x0	
Access Type		Write, Read		Write, Read		Write,	Read	Write, Read	Write, Read	
BITFIELD	BITS	DESCRIPTION				DECODE				
seq_set	7:5	Sequence s	Sequence selection bits.			0x0: Sec 0x1: Sec 0x2: Sec 0x3: Sec 0x4: Sec 0x5: Sec 0x6: Sec 0x7: Sec	quence 1 quence 2 quence 3 quence 4 quence 5 quence 6 quence 7 quence 8			
pfo_th	4	This bit sets the PFO out	the nominal fa put.	lling threhsold f	for	0x0: 2.5 0x1: 2.4	V V			
tstart	3:2	This field se VG _{OFF} betw startup is ac or 4ms.	This field sets the start-up time for VG _{ON} and VG _{OFF} between 1ms and 8ms. The AVDD startup is accordingly set to 0.5ms, 1ms, 2ms, or 4ms.			0x0: 1m 0x1: 2m 0x2: 4m 0x3: 8m	s s s			
lxp_lim_low	1	When 1, the limit is reduce	When 1, the HVINP boost converter current limit is reduced.							
start	0	When this b are turned o by the seq_s	When this bit is set to 1, the device outputs are turned on in the sequence programmed by the seq_set bits in the SEQ register.							

ISET (0x0A)

BIT	7	6	5	4		3	2		1	0	
Field	_	iset[6:0]									
Reset	_										
Access Type	_		Write, Read								
BITFIELD	BITS		DESCRIPTION DECODE								
iset	6:0	The value in current in th	this register s e 23mA to 150	ets the OUT_ L mA range.	ED	0x0: 23n 0x1: 24n : 0xB: 34r 0xC: 35r : 0x7D: 14 0x7E: 14 0x7F: 15	nA nA nA mA 48mA 49mA 50mA				

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BL_CONFIG1 (0x0B)

BIT	7	6	5	4		3	2	1	0		
Field	dim_ext	hdim	hdim_	thr[1:0]	bs	stforce	fast_ss	psen	fltb_mode		
Reset	0x1	0x0	0x	:00		0x0	0x0	0x1	0x0		
Access Type	Write, Read	Write, Read	Write, Read Write			te, Read	Write, Read	Write, Read	Write, Read		
BITFIELD	BITS		DESCRIPTION			DECODE					
dim_ext	7	When 1, dim enabled. Wh the TON r	en 1, dimming through the DIM pin is abled. When 0, dimming is controlled using TONregisters.								
hdim	6	When 1, hyt	When 1, hybrid dimming is enabled.								
hdim_thr	5:4	Set hybrid-d is 6.25% (00	Set hybrid-dimming threshold. Default value s 6.25% (00).				25% 2.5% 5% 0%				
bstforce	3	When 1, this run continuc dimming sig	s bit forces the busly, independ nal.	boost converte lently of the	r to						
fast_ss	2	Selects slow for fast soft-	/ or fast boost s start.	soft-start. Set to	o 1						
psen	1	When 0, pha phase shiftir	ase shifting is c ng is enabled.	lisabled. When	1,						
fltb_mode	0	This bit sets FLTB pin in FLTB output type of fault. fault is detect	This bit sets the mode of operation of the FLTB pin in standalone mode. When 0, the FLTB outputs a PWM signal to indicate the type of fault. When 1, FLTB is low when a fault is detected								

BL_CONFIG2 (0x0C)

BIT	7	6	5	4		3	2	1	0	
Field	bl_ilim		fpwm[2:0]		bl	_ss_off	bl_ssl	bl_ssl sldet[1:0]		
Reset	0x1	0x001				0x0	0x0	0x	00	
Access Type	Write, Read		Write, Read			e, Read Write, Read		Write,	Read	
BITFIELD	BITS		DESCRIPT	ION			DI	ECODE		
bl_ilim	7	Sets boost of When 1, the	ts boost current limit to one of two levels. hen 1, the lower current limit is selected.							
fpwm	6:4	These bits s PWM mode	bits set the PWM frequency in internal node.				8Hz 8Hz 5Hz 0Hz 20Hz 01Hz 84Hz			
bl_ss_off	3	When 1, spr disabled.	When 1, spread-spectrum switching is disabled.							

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BITFIELD	BITS	DESCRIPTION	DECODE
bl_ssl	2	When spread spectrum is enabled, the bl_ssl bit chooses the amount of spread: When 0, the spread is nominally $\pm 6\%$; when 1, the spread is $\pm 3\%$. When changing the percentage, first disable spread spectrum using the SS_OFF bit, then change the value of SSL, and finally reenable spread spectrum using SS_OFF.	
sldet	1:0	Shorted-LED threshold settings.	0x0: Disabled 0x1: 3V 0x2: 6V 0x3: 8V

BL_DIS (0x0D)

BIT	7	6	5		4	3	2	1	0	
Field	cp_dis	-	dis_	bl	dis6	dis5	dis4	dis3	dis2	
Reset	0x0	-	0x	0	0x0	0x0	0x0	0x0	0x0	
Access Type	Write, Re	Read – Write, Read Write, Read Write, Read			Write, Read	Write, Read	Write, Read			
BITFIEI	_D	BITS		DESCRIPTION						
cp_dis		7		When 1, this bit disables the internal charge pump which drives the NG pin. Set to 1 when an external series switch is not used. Setting CP_DI during operation will cause complete shutdown of the device and is not recommended.						
dis_bl		5		Disab	le bit for backli	ght section.				
dis6		4		Set th 1.	his bit to 1 to dis	sable OUT6. TI	his must be do	ne before ENA	is written to	
dis5		3		Set th 1.	his bit to 1 to dis	sable OUT5. TI	his must be do	ne before ENA	is written to	
dis4		2		Set this bit to 1 to disable OUT4. This must be done before ENA is written to 1.						
dis3		1		Set this bit to 1 to disable OUT3. This must be done before ENA is written to 1.						
dis2		0		Set th 1.	his bit to 1 to dis	sable OUT2. TI	his must be do	ne before ENA	is written to	

BL_FADING (0x0E)

BIT	7	6	5	4		3	2	1	0
Field	_	_	-	fade_gain	fade	e_in_out	tfade[2:0]		
Reset	_	-	_	0b0		0b0	0x0		
Access Type	_	_	_	Write, Read	Write, Read		Write, Read		
BITFIELD	BITS		DESCRIPT	DESCRIPTION DECODE					
fade_gain	4	When this b function has 6.25%.	it is set to 1, the a gain of 12.5°	e fade-in-out %, otherwise					
fade_in_out	3	When this b function for	it is set to 1, the the LED dimmi	e fade-in-out ng is enabled.					

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BITFIELD	BITS	DESCRIPTION	DECODE
tfade	2:0	Sets the fading update time interval according to 2 ^{TDIM} . TDIM can be between 0 and 5. When set to 0, fading is updated on every dimming cycle.	0x1: 2 0x2: 4 0x3: 8 0x4: 16 0x5: 32 0x6: N/A 0x7: N/A

CUSTOMER_USE1 (0x0F)

Register which can be used to store user data that can also be stored in nonvolatile memory.

BIT	7	6	5	4	3	2	1	0		
Field		customer_use1[7:0]								
Reset										
Access Type		Write, Read								
BITFIEL	D	D BITS DESCRIPTION								
customer_use1	7:0									

CUSTOMER_USE2 (0x10)

Register which can be used to store user data that can also be stored in nonvolatile memory.

BIT	7	6	5	4	3	2	1	0		
Field		customer_use2[7:0]								
Reset										
Access Type		Write, Read								
BITFIEI	D	BITS DESCRIPTION								
customer_use2	2	7:0								

CUSTOMER_USE3 (0x11)

Register which can be used to store user data that can also be stored in nonvolatile memory.

BIT	7	6	5	4	3	2	1	0	
Field	customer_use3[7:0]								
Reset									
Access Type		Write, Read							
BITFIEI	D	D BITS DESCRIPTION							
customer_use3	3	7:0							

CUSTOMER_USE4 (0x12)

Register which can be used to store user data that can also be stored in nonvolatile memory.

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BIT	7	6	5	4	3	2	1	0		
Field		customer_use4[7:0]								
Reset										
Access Type		Write, Read								
BITFIEI	D	BITS		DESCRIPTION						
customer_use4	L I	7:0								

AVDD_SET (0x13)

BIT	7	6	5	4	3	2	1	0		
Field	-	-		avdd[5:0]						
Reset	-	-		0x1A						
Access Type	-	-		Write, Read						

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BITFIELD	BITS	DESCRIPTION					
		Sets AVDD ar dis navdd bit,	nd NAVDD voltages. When NAV the voltage values represented	DD is disabled using the by the avdd bits change.			
		Value	dis_navdd = 1	dis_navdd = 0			
		0x0	11.7	N/A			
		0x1	11.8	N/A			
		0x2	11.9	N/A			
		0x3	12	N/A			
		0x4	12.1	N/A			
		0x5	12.2	N/A			
		0x6	12.3	N/A			
		0x7	12.4	4.9			
		0x8	12.5	5			
		0x9	12.6	5.1			
		0xA	12.7	5.2			
		0xB	12.8	5.3			
		0xC	12.9	5.4			
		0xD	13	5.5			
		0xE	13.1	5.6			
		0xF	13.2	5.7			
		0x10	13.3	5.8			
		0x11	13.4	5.9			
avdd	5:0	0x12	13.5	6			
		0x13	13.6	6.1			
		0x14	13.7	6.2			
		0x15	13.8	6.3			
		0x16	13.9	6.4			
		0x17	14	6.5			
		0x18	14.1	6.6			
		0x19	14.2	6.7			
		0x1A	14.3	6.8			
		0x1B	14.4	6.9			
		0x1C	14.5	7V			
		0x1D	14.6	7.1			
		0x1E	14.7	7.2			
		0x1F	14.8	7.3			
		0x20	14.9	7.4			
		0x21	15	7.5			
		0x22	15.1	7.6			
		0x23	15.2	7.7			
		0x24	15.3	7.8			
		0x25	15.4	7.9			
		0x26	15.5	8			

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BITFIELD	BITS		DESCRIPTION	1
		0x27	15.6	8.1
		0x28	15.7	8.2
		0x29	15.8	8.3
		0x2A	15.9	8.4
		0x2B	16	8.5
		0x2C	16.1	8.6
		0x2D	16.2	8.7
		0x2E	16.3	8.8
		0x2F	16.4	8.9
		0x30	16.5	9
		0x31	16.6	9.1
		0x32	16.7	9.2
		0x33	16.8	9.3
		0x34	16.9	9.4
		0x35	17	9.5
		0x36	17.1	9.6
		0x37	17.2	9.7
		0x38	17.3	9.8
		0x39	17.4	9.9
		0x3A	17.5	10
		0x3B	17.6	10.1
		0x3C	17.7	10.2
		0x3D	17.8	10.3
		0x3E	17.9	10.4
		0x3F	18	10.5

VGON (0x14)

BIT	7	6	5	4	3	2	1	0		
Field	_	_	vgon[5:0]							
Reset	-	-		0x16						
Access Type	-	_		Write, Read						

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BITFIELD	BITS	DESCRIPTION					
		Sets VG _{ON} voltage.					
		Value	dis_navdd = 0	dis_navdd = 1			
		0x0	8.4	12.6			
		0x1	8.6	12.9			
		0x2	8.8	13.2			
		0x3	9	13.5			
		0x4	9.2	13.8			
		0x5	9.4	14.1			
		0x6	9.6	14.4			
		0x7	9.8	14.7			
		0x8	10	15			
		0x9	10.2	15.3			
		0xA	10.4	15.6			
		0xB	10.6	15.9			
		0xC	10.8	16.2			
		0xD	11	16.5			
		0xE	11.2	16.8			
		0xF	11.4	17.1			
		0x10	11.6	17.4			
		0x11	11.8	17.7			
		0x12	12	18			
vgon	5:0	0x13	12.2	18.3			
		0x14	12.4	18.6			
		0x15	12.6	18.9			
		0x16	12.8	19.2			
		0x17	13	19.5			
		0x18	13.2	19.8			
		0x19	13.4	20.1			
		0x1A	13.6	20.4			
		0x1B	13.8	20.7			
		0x1C	14	21			
		0x1D	14.2	21.3			
		0x1E	14.4	21.6			
		0x1F	14.6	21.9			
		0x20	14.8	22.2			
		0x21	15	22.5			
		0x22	15.2	22.8			
		0x23	15.4	23.1			
		0x24	15.6	23.4			
		0x25	15.8	23.7			
		0x26	16	24			
		0x27	16.2	24.3			

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BITFIELD	BITS		DESCRIPTION	
		0x28	16.4	24.6
		0x29	16.6	24.9
		0x2A	16.8	25.2
		0x2B	17	25.5
		0x2C	17.2	25.8
		0x2D	17.4	26.1
		0x2E	17.6	26.4
		0x2F	17.8	26.7
		0x30	18	27
		0x31	18.2	27.3
		0x32	18.4	27.6
		0x33	18.6	27.9
		0x34	18.8	28.2
		0x35	19	28.5
		0x36	19.2	28.8
		0x37	19.4	29.1
		0x38	19.6	29.4
		0x39	19.8	29.7
		0x3A	20	30
		0x3B	20.2	30.3
		0x3C	20.4	30.6
		0x3D	20.6	30.9
		0x3E	20.8	31.2
		0x3F	21	31.5

VGOFF (0x15)

BIT	7	6	5	4	3	2	1	0						
Field	-	-		vgoff[5:0]										
Reset	—	-		0x16										
Access Type	-	_			Write,	Read		Write, Read						

Automotive, I²C-Controlled, 6-Channel, 150mA Backlight Driver and 4-Output TFT-LCD Bias

BITFIELD	BITS	DESCRIPTION	DECODE
vgoff	5:0	Sets VG _{OFF} voltage.	0x0: -4 $0x1: -4.25$ $0x2: -4.5$ $0x3: -4.75$ $0x4: -5$ $0x5: -5.25$ $0x6: -5.5$ $0x7: -5.75$ $0x8: -6$ $0x9: -6.25$ $0xA: -6.5$ $0x8: -6.75$ $0xC: -7$ $0xD: -7.25$ $0xF: -7.75$ $0x11: -8$ $0x11: -9$ $0x15: -9.25$ $0x14: -9$ $0x15: -9.25$ $0x14: -10.5$ $0x12: -12.5$ $0x22: -12.5$

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BITFIELD	BITS	DESCRIPTION	DECODE
			0x3B: Do not use 0x3C: Do not use 0x3D: Do not use 0x3E: Do not use 0x3F: Do not use

NV_CONFIG (0x17)

Nonvolatile configuration register

BIT	7	6	5	4	3	2	1	0	
Field	nv_dis_nav dd	nv_refresh	nv_en_ss	nv_fSW	nv_tre	nv_tretry[1:0]		nv_tfault[1:0]	
Reset	0x1	0x1	0x1	0x1	0	x3	0:	x3	
Access Type	Read Only	Read Only	Read Only	Read Only	Read	Read Only		Read Only	
BITFIELD	BITS		DESCRIPT	ION		DECODE			
nv_dis_navd d	7	NV setting for	or dis_navdd						
nv_refresh	6	NV setting for	or refresh bit						
nv_en_ss	5	NV setting for	or en_ss bit						
nv_fSW	4	NV setting for	or fSW bit		0x0: 2.2 0x1: 440	MHz)kHz			
nv_tretry	3:2	NV setting for	or tretry bits						
nv_tfault	1:0	NV setting for	NV setting for tfault bits						

NV_DELAY (0x18)

BIT	7	6	5		4 3 2		1	0	
Field	nv_de	ıv_delayt1[1:0] n		_dela	ayt2[1:0]	nv_de	layt3[1:0]	unused	nv_par_en
Reset		0x3		0:	x3		Dx3	0x1	0x1
Access Type	Rea	ad Only		Read	l Only	Rea	Read Only		Read Only
BITFIEI	D	BITS		DESCRIPTION					
nv_delayt1		7:6		NV se	etting for delay	t1			
nv_delayt2		5:4		NV se	etting for delay	12			
nv_delayt3		3:2		NV setting for delayt3					
unused		1							
nv_par_en		0		NV setting for par_en bit					

NV_SEQ (0x19)

BIT	7	6	5	4	3	2	1	0
Field	nv_seq_set[2:0]			nv_pfo_th	nv_tsta	art[1:0]	nv_lxp_lim_l ow	nv_start
Reset	0x7			0x1	0:	(3	0x1	0x1
Access Type		Read Only Read Only Read Or		Only	Read Only	Read Only		

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BITFIELD	BITS	DESCRIPTION
nv_seq_set	7:5	NV setting for seq_set bits
nv_pfo_th	4	NV setting for pfo_th bit
nv_tstart	3:2	NV setting for tstart bits
nv_lxp_lim_low	1	NV setting for lxp_lim_low bit
nv_start	0	NV setting for start bit

NV_ISET (0x1A)

BIT	7	6	6 5 4 3 2 1 0							
Field	unused		nv_iset[6:0]							
Reset	0x1		0x7F							
Access Type	Read On	ly	Read Only							
BITFIEI	LD	BITS			DE	SCRIPTION				
unused		7								
nv_iset		6:0	NV L	NV LED current setting						

NV_BL_CONFIG1 (0x1B)

BIT	7		6	5	5 4		3	2	1	0	
Field	nv_dim_e	ext	nv_hdim	nv_hdim_thr[1:0]		nv_bstforce	nv_fast_ss	nv_psen	nv_fltb_mod e		
Reset	0x1		0x1		0:	x3	0x1	0x1	0x1	0x1	
Access Type	Read Or	nly	Read Only		Read	l Only	Read Only	Read Only	Read Only	Read Only	
BITFIE	LD		BITS		DESCRIPTION						
nv_dim_ext			7		NV se	etting for dim_e	ext bit				
nv_hdim			6		NV se	etting for hdim l	oit				
nv_hdim_thr			5:4		NV se	etting for hdim_	thr bits				
nv_bstforce			3		NV setting for bstfor		ce bit				
nv_fast_ss			2		NV setting for fast_ss bit			NV setting for fast_s			
nv_psen			1		NV setting for psen bit				NV setting for psen		
nv_fltb_mode			0		NV se	etting for fltb_m	ode bit				

NV_BL_CONFIG2 (0x1C)

BIT	7	6	6 5 4			2	1	0
Field	nv_bl_ilin	1	nv_fpwm[2:0]			nv_bl_ssl	nv_sld	let[1:0]
Reset	0x1		0x7			0x1	0)	x3
Access Type	Read Onl	y	Read Only		Read Only	Read Only	Read	l Only
BITFIEI	LD	BITS			DE	SCRIPTION		
nv_bl_ilim		7	NV s	NV setting for bl_ilim bit				
nv_fpwm		6:4	NV s	NV setting for fpwm bits				

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BITFIELD	BITS	DESCRIPTION
nv_bl_ss_off	3	NV setting for bl_ss_off bit
nv_bl_ssl	2	NV setting for bl_ssl bit
nv_sldet	1:0	NV setting for shorted-LED threshold

NV_BL_DIS (0x1D)

BIT	7	6	5		4	3	2	1	0
Field	nv_cp_di	s unused	nv_di	s_bl	nv_dis6	nv_dis5	nv_dis4	nv_dis3	nv_dis2
Reset	0x1	0x1	0x	1	0x1	0x1	0x1	0x1	0x1
Access Type	Read Onl	y Read Only	Read	Only	Read Only	Read Only	Read Only	Read Only	Read Only
BITFIEI	LD	BITS				DE	SCRIPTION		
nv_cp_dis		7		NV se	etting for cp_dis	s bit			
unused		6							
nv_dis_bl		5		NV se	etting for dis_bl	bit			
nv_dis6		4		NV se	etting for dis6 b	it			
nv_dis5		3		NV se	etting for dis5 b	it			
nv_dis4		2		NV setting for dis4 bit					
nv_dis3		1		NV setting for dis3 bit					
nv_dis2		0		NV se	etting for dis2 b	it			

NV_BL_FADING (0x1E)

BIT	7	6	5	4	3	2	1	0	
Field		unused[2:0]		nv_fade_gai n	nv_fade_in_ out		nv_tfade[2:0]		
Reset		0x7		0x1	0x1		0x7		
Access Type		Read Only		Read Only	Read Only	Read Only			
BITFIEI	LD	BITS			DE	SCRIPTION			
unused		7:5							
nv_fade_gain		4	NV :	NV setting for fade_gain bit					
nv_fade_in_ou	t	3	NV :	NV setting for fade_in_out					
nv_tfade		2:0	NV :	NV setting for tfade bits					

NV_CUSTOMER_USE1 (0x1F)

Register which can be used to store user data.

BIT	7	6	5	4	3	2	1	0			
Field		nv_customer_use1[7:0]									
Reset				0>	٢ff						
Access Type		Read Only									
BITFIEI	LD	D BITS DESCRIPTION									
nv_customer_u	se1 7:0										

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NV_CUSTOMER_USE2 (0x20)

Register which can be used to store user data.

BIT	7	6	5	4	3	2	1	0		
Field		nv_customer_use2[7:0]								
Reset				0>	cff					
Access Type		Read Only								
BITFIEI	D BITS DESCRIPTION									
nv_customer_u	se2 7:0									

NV_CUSTOMER_USE3 (0x21)

Register which	n can be us	ed to store user	data.								
BIT	7	7 6 5 4 3 2 1 0									
Field		nv_customer_use3[7:0]									
Reset		Oxff									
Access Type				Read	Only						
BITFIEI	D BITS DESCRIPTION										
nv_customer_u	se3 7:0										

NV_CUSTOMER_USE4 (0x22)

Register which can be used to store user data

BIT	7	6	5	4	3	2	1	0		
Field		nv_customer_use4[7:0]								
Reset				0)	٢ff					
Access Type		Read Only								
BITFIEI	LD	BITS DESCRIPTION								
nv_customer_u	se4 7:0									

NV_AVDD_SET (0x23)

BIT	7	6	5	4	3	2	1	0	
Field	unuse	ed[1:0]		nv_avdd[5:0]					
Reset	0	x3			0:	x3f			
Access Type	Read Only				Read	d Only			
BITFIEI	D	BITS			DE	SCRIPTION			
unused		7:6							
nv_avdd	5:0		NV s	NV setting for avdd bits					

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NV_VGON (0x24)

BIT	7	6	5	4	3	2	1	0				
Field	unus	ed[1:0]	nv_vgon[5:0]									
Reset	C	x3		0x3f								
Access Type	Rea	d Only		Read Only								
BITFIEI	_D	BITS		DESCRIPTION								
unused		7:6										
nv_vgon	5:0		5:0 NV setting for vgon bits				NV setting for vgon bits					

NV_VGOFF (0x25)

BIT	7	6	5		4	3	2	1	0		
Field	unus	ed[1:0]		nv_vgoff[5:0]							
Reset	0x3					0	x3f				
Access Type	Read	d Only		Read Only							
BITFIEI	LD	BITS		DESCRIPTION							
unused		7:6									
nv_vgoff		5:0		NV setting for vgoff bits							

AVDD_LIM (0x26)

BIT	7	6	5	4	3	2	1	0		
Field	-	-		avdd_lim[5:0]						
Reset	_	-			0x	3F				
Access Type	_	-		Write, Read						
BITFIE	LD	BITS		DESCRIPTION						
avdd_lim		5:0	Maximum limit setting for avdd. To use this function, write to this register before setting avdd. An avdd setting above avdd_lim will not be accepted.							

LO_DIM (0x27)

BIT	7		6	5		4	3	2	1	0
Field	ton_mast	ter	_	– lo_dir		lo_dim5	lo_dim4	lo_dim3	lo_dim2	lo_dim1
Reset	0x0		-	0x	0	0x0	0x0	0x0	0x0	0x0
Access Type	Write, Re	ad	-	Read	Read Only Read Only Read Only Read O				Read Only	Read Only
BITFIE	LD		BITS		DESCRIPTION					
ton_master			7		Wher (TON	this bit is set, 1H:TON1L:TO	the 18-bit PWN N1LSB) applies	I setting for chains to all 6 chann	annel 1 iels.	
lo_dim6			5		When 1, indicates that channel 6 is in low-dim mode.					
lo_dim5			4		When 1, indicates that channel 5 is in low-dim mode.					
lo_dim4			3		Wher	1, indicates th	at channel 4 is	in low-dim mo	de.	

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BITFIELD	BITS	DESCRIPTION
lo_dim3	2	When 1, indicates that channel 3 is in low-dim mode.
lo_dim2	1	When 1, indicates that channel 2 is in low-dim mode.
lo_dim1	0	When 1, indicates that channel 1 is in low-dim mode.

TON1H (0x28)

BIT	7	6	5	4	3	2	1	0			
Field	ton1h[7:0]										
Reset		0xFF									
Access Type		Write, Read									
BITFIEI	LD	D BITS DESCRIPTION									
ton1h		7:0	Mos in 50	Most significant byte of 18-bit on-time setting for channel 1. This value is set in 50ns units.							

TON1L (0x29)

BIT	7	6	5	4	3	2	1	0		
Field	ton1l[7:0]									
Reset		0xFF								
Access Type	Write, Read									
BITFIEI	LD	D BITS DESCRIPTION								
ton1l		7:0	Least significant byte of 18-bit on-time setting for channel 1. This value is set in 50ns units.							

TON2H (0x2A)

BIT	7	6	5	4	3	2	1	0			
Field	ton2h[7:0]										
Reset		0xFF									
Access Type		Write, Read									
BITFIEI	LD	D BITS DESCRIPTION									
ton2h		7:0	:0 Most significant byte of 18-bit on-time setting for channel 2. This value is set in 50ns units.								

TON2L (0x2B)

BIT	7	6	5	4	3	2	1	0		
Field		ton2l[7:0]								
Reset		0xFF								
Access Type				Write,	Read					

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BITFIELD	BITS	DESCRIPTION
ton2l	7:0	Least significant byte of 18-bit on-time setting for channel 2. This value is set in 50ns units.

TON3H (0x2C)

BIT	7	6	5	4	3	2	1	0			
Field	ton3h[7:0]										
Reset		0xFF									
Access Type		Write, Read									
BITFIEI	D	D BITS DESCRIPTION									
ton3h		7:0 Most significant byte of 18-bit on-time setting for channel 3. This value is set in 50ns units.									

TON3L (0x2D)

BIT	7	6	5	4	3	2	1	0		
Field	ton3l[7:0]									
Reset		0xFF								
Access Type		Write, Read								
BITFIEI	LD	D BITS DESCRIPTION								
ton3l	7:0 Least significant byte of 18-bit on-time setting for channel 3. This value is set in 50ns units.							value is set		

TON1_3LSB (0x2E)

BIT	7	6	5	4	3	2	1	0		
Field	-	-	ton3lsb[1:0] ton2lsb[1:0] ton1lsb[sb[1:0]					
Reset	-	-	0:	0x3 0x3 0x3		x3				
Access Type	_	_	Write	Write, Read Write, Read		Write,	, Read			
BITFIE	LD	BITS			DE	SCRIPTION				
ton3lsb		5:4	Least in 50	t significant bits ns units.	of 18-bit on-tir	ne setting for c	hannel 3. This	value is set		
ton2lsb		3:2	Least in 50	ast significant bits of 18-bit on-time setting for channel 2. This value is set 50ns units.						
ton1lsb		1:0	Least in 50	t significant bits ns units.	of 18-bit on-tir	ne setting for c	setting for channel 1. This value is set			

TON4H (0x2F)

BIT	7	6	5	4	3	2	1	0		
Field		ton4h[7:0]								
Reset		0xFF								
Access Type				Write,	Read					

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BITFIELD	BITS	DESCRIPTION
ton4h	7:0	Most significant byte of 18-bit on-time setting for channel 4. This value is set in 50ns units.

TON4L (0x30)

BIT	7	6	5	4	3	2	1	0		
Field	ton4l[7:0]									
Reset		0xFF								
Access Type	Write, Read									
BITFIEI	D	BITS			DE	SCRIPTION				
ton4l		7:0	Leas in 50	Least significant byte of 18-bit on-time setting for channel 4. This value is se in 50ns units.						

TON5H (0x31)

BIT	7	6	5	4	3	2	1	0		
Field		ton5h[7:0]								
Reset		0xFF								
Access Type		Write, Read								
BITFIEI	LD	BITS			DE	SCRIPTION				
ton5h		7:0	Most in 50	Most significant byte of 18-bit on-time setting for channel 5. This value is set in 50ns units.						

TON5L (0x32)

BIT	7	6	5	4	3	2	1	0		
Field	ton5l[7:0]									
Reset		0xFF								
Access Type	Write, Read									
BITFIEI	LD	BITS			DE	SCRIPTION				
ton5l		7:0	Leas in 50	Least significant byte of 18-bit on-time setting for channel 5. This value is se in 50ns units.						

TON6H (0x33)

BIT	7	6	5	4	3	2	1	0			
Field				ton6l	n[7:0]						
Reset		0xFF									
Access Type		Write, Read									
BITFIEL	D	BITS			DE	SCRIPTION					
ton6h		7:0	Most in 50	significant byte ns units.	of 18-bit on-ti	me setting for c	hannel 6. This	value is set			

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TON6L (0x34)

BIT	7	6	5	4	3	2	1	0	
Field				ton6	[7:0]				
Reset	0xFF								
Access Type	Write, Read								
BITFIEI	LD	BITS			DE	SCRIPTION			
ton6l		7:0	Leas in 50	t significant byte ns units.	e of 18-bit on-t	ime setting for	channel 6. This	value is set	

TON4_6LSB (0x35)

BIT	7	6	5	4	3	2	1	0		
Field	-	-	ton6lsb[1:0] ton5lsb[1:		sb[1:0]	ton4lsb[1:0]				
Reset	_	-	0	x3	0:	x3	0x3			
Access Type	_	-	Write	Write, Read Write, Read		Write,	Read			
BITFIE	LD	BITS			DE	SCRIPTION				
ton6lsb		5:4	Leas in 50	t significant bits ns units.	of 18-bit on-tir	ne setting for c	hannel 6. This	value is set		
ton5lsb		3:2	Leas in 50	Least significant bits of 18-bit on-time setting for channel 5. This value is set in 50ns units.						
ton4lsb		1:0	Leas in 50	east significant bits of 18-bit on-time setting for channel 4. This value is set n 50ns units.						

OPEN_REG (0x36)

BIT	7	6	5		4	3	2	1	0	
Field	_	-	out	60	out5o	out4o	out3o	out2o	out1o	
Reset	-	_	0x	0	0x0	0x0	0x0	0x0	0x0	
Access Type	-	_	Re: Clear	ad 's All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	
BITFIELD BITS DESCRIPTION										
out6o		5 When 1, this bit indicates an open-circuit condition on OUT6.								
out5o		4		Wher	n 1, this bit indio	cates an open-	circuit conditior	ו on OUT5.		
out4o		3		Wher	n 1, this bit indio	cates an open-	circuit conditior	n on OUT4.		
out3o	2 When 1, this bit indicates an open-circuit condition on OUT				n on OUT3.					
out2o	ut2o 1 V			Wher	When 1, this bit indicates an open-circuit condition on OUT2.					
out1o		0		Wher	n 1, this bit indio	cates an open-	circuit conditior	n on OUT1.		

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SHORTGND_REG (0x37)

BIT	7	6	5	;	4	3	2	1	0	
Field	_	_	oute	Ssg	out5sg	out4sg	out3sg	out2sg	out1sg	
Reset	_	_	0x	:0	0x0	0x0	0x0	0x0	0x0	
Access Type	_	-	Re Clear	ad ˈs All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	
BITFIELD BITS DESCRIPTION										
out6sg		5		Wher	When 1, this bit indicates a short-to-ground condition on OUT6.					
out5sg		4		Wher	n 1, this bit indio	cates a short-to	-ground condit	ion on OUT5.		
out4sg		3		Wher	n 1, this bit indio	cates a short-to	-ground condit	ion on OUT4.		
out3sg	2				When 1, this bit indicates a short-to-ground condition on OUT3.					
out2sg	sg 1 When				When 1, this bit indicates a short-to-ground condition on OUT2.					
out1sg		0		Wher	n 1, this bit indic	cates a short-to	-ground condit	ion on OUT1.		

SHORTED_LED_REG (0x38)

BIT	7	6	5		4	3	2	1	0
Field	-	-	oute	Ssl	out5sl	out4sl	out3sl	out2sl	out1sl
Reset	-	-	0x(0	0x0	0x0	0x0	0x0	0x0
Access Type	_	-	Rea Clears	ad s All	Read Sets All	Read Clears All	Read Clears All	Read Clears All	Read Clears All
BITFIELD BITS DESCRIPTION									
out6sl		5	5 When 1, this bit indicates a shorted-LED condition on OUT6.						
out5sl		4		Wher	1, this bit indic	cates a shorted	-LED conditior	on OUT5.	
out4sl		3		Wher	1, this bit indic	cates a shorted	-LED condition	on OUT4.	
out3sl		2	When 1, this bit indicates a shorted-LED condition on OUT3.						
out2sl		1	1 When 1, this bit indicates a shorted-LED condition on OUT2.						
out1sl		0		When	1, this bit indic	ates a shorted	-LED condition	on OUT1.	

BL_MASK (0x39)

BIT	7	6	5		4	3	2	1	0	
Field	– battuv		battuvmask		bstuvmask	omask	sgmask	bl_otwmask	slmask	
Reset	-		0x1		0x0	0x0	0x0	0x1	0x0	
Access Type	_	Read Clears All	Write,	Read	Write, Read	Write, Read	Write, Read	Write, Read	Write, Read	
BITFIELD BITS				DESCRIPTION						
battuv		6		This bit indicates an undervoltage on the BATT pin, which causes the backlight boost to be disabled.					s the	
battuvmask		5		Mask bit for BATT undervoltage indication. When 1, an undervoltage on BA does not cause FLTB to assert low.					age on BATT	
bstuvmask		4		Mask bit for boost undervoltage indication. When 1, an undervoltage or boost output does not cause FLTB to assert low.				age on the		
omask		3		Mask bit for open-LED indication.						
sgmask		2		Mask	bit for short-to-	-GND indication	n.			

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BITFIELD	BITS	DESCRIPTION				
bl_otwmask	1	When 1, this bit prevents a backlight overtemperature warning from asserting the FLTB pin low.				
slmask	0	Mask bit for shorted-LED indication.				

BL_DIAG (0x3A)

BIT	7	6	6 5		4	3	2	1	0	
Field	_	rtoor	irefoor		bstuv	bstov	hw_rst	bl_otw	bl_ot	
Reset	-	0x0	0x0		0x0	0x0	0x1	0x0	0x0	
Access Type	_	Read Clears All	Rea Clear	ad s All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	Read Clears All	
BITFIEI	D	BITS			DESCRIPTION					
rtoor	rtoor			When set to 1, this bit indicates that the resistor on RT is out of the prescril range.						
irefoor 5				When 1, this bit indicates that the IREF current is too high. This is probably due to an incorrect resistor value on IREF. In this condition, the IC stops operation.						
bstuv 4				If 1, an undervoltage has been detected on the boost output and the boost was disabled.						
bstov		3		If 1, the boost converter is at its overvoltage limit.						
hw_rst 2		2		If 1, the device has just emerged from a hardware reset (power-up). This bit reset after the first read from this register.					ıp). This bit is	
bl_otw 1			If 1, the temperature of the backlight section is over +125°C or the temperature foldback circuit has reached the temperature T1.							
bl_ot		0	0		If 1, the temperature of the backlight section exceeded +165°C and the backlight block was shut down or the TEMP input reached the level that shuts off the LED currents.					

burn_otp_reg (0x78)

BIT	7	6	5	4	3	2	1	0			
Field	burn_otp[7:0]										
Reset	0x0										
Access Type	Write Only										
BITFIELD BITS DESCRIPTION											
burn_otp 7:0			Com regis the c	Command to copy the contents of registers 0x07–0x15 to the nonvolatile registers 0x17–0x25. Send the data 8'hA5 after the address 8'h78 to enable the command.							

reboot_otp_reg (0x79)

BIT	7	6	5	4	3	2	1	0	
Field	reboot_otp[7:0]								
Reset									
Access Type				Write	Only				

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BITFIELD	BITS	DESCRIPTION
reboot_otp	7:0	Command to copy the contents of the nonvolatile registers 0x17–0x15 to the working registers 0x17–0x25. Send the data 8'h5A after the address 8'h79 to enable the command.

soft_restart (0x7A)

BIT	7	6	5	4	3	2	1	0			
Field	soft_restart[7:0]										
Reset	0x00										
Access Type	Write Only										
BITFIEI	BITFIELD BITS DESCRIPTION										
soft_restart		7:0	Com clear addre	Command used to restart the device from a latched fault mode. All faul cleared when this command is executed. Send the data 8'hC3 after the address 8'h7A to enable the command.							

Applications Information

TFT Power Section

AVDD Boost Converter

Boost Converter Inductor Selection

Three key inductor parameters must be specified for operation with the device: inductance value (L), inductor saturation current (I_{SAT}), and DC resistance (R_{DC}). Use a 2.2µH inductor when the boost converter operates at 2.1MHz and 10µH at 420kHz. In unipolar mode, use a 3.3µH inductor at 2.1MHz.

The inductor's saturation rating must exceed the maximum LXP current limit.

Boost Output-Filter Capacitor Selection

The primary criterion for selecting the output-filter capacitor is low effective series resistance (ESR). The product of the peak inductor current and the output filter capacitor's ESR determine the amplitude of the high-frequency ripple seen on the output voltage. For stability, the boost output-filter capacitor should have a value of 10μ F or greater at 2.1MHz and 20μ F at 420kHz.

To avoid a large drop on HVINP when NAVDD is enabled, the capacitance on the HVINP node should be larger than that on NAVDD.

Boost Converter External Diode Selection

Select a diode with a peak current rating of at least the LXP current limit for use with the HVINP output. The diode breakdown-voltage rating should exceed the absolute value of the HVINP voltage. A Schottky diode improves the overall efficiency of the converter, but should be selected to have low leakage at the maximum operating temperature.

Setting the AVDD Voltage

The AVDD output is set by writing a 6-bit value to the avdd[5:0] field in the AVDD_SET register (address 0x13). The output voltage also depends on the setting of the dis_navdd bit in the TFT_CONFIG register (address 0x07).

NAVDD Inverting Regulator

The NAVDD converter outputs a negative voltage whose absolute value is the same as AVDD. The most negative voltage NAVDD can output is -10.5V. NAVDD can be disabled using the dis_navdd bit in the TFT_CONFIG register.

NAVDD Regulator Inductor Selection

Three key inductor parameters must be specified for operation with the device: inductance value (L), inductor saturation current (I_{SAT}), and DC resistance (R_{DC}). Use a 2.2µH inductor when the converter operates at 2.1MHz and 10µH at 420kHz.

The inductor's saturation current rating must exceed the maximum LXN current limit.

NAVDD External Diode Selection

Select a diode with a peak current rating of at least the LXN current limit for use with the NAVDD output. The diode breakdown-voltage rating should exceed the sum of the maximum INN voltage and the absolute value of the NAVDD voltage. A Schottky diode improves the overall efficiency of the converter.

NAVDD Output Capacitor Selection

The primary criteria for selecting the output filter capacitor are low ESR and capacitance values, as the NAVDD capacitor provides the load current when the internal switch is on. The voltage ripple on the NAVDD output has two components:

- Ripple due to ESR, which is the product of the peak inductor current and the output filter capacitor's ESR
- Ripple due to bulk capacitance, which can be determined as follows:

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$$\Delta V_{\text{BULK}} = \frac{I_{\text{NAVDDG}} \times \frac{D}{f_{\text{SW}}}}{C_{\text{NAVDD}}}$$

For stability, the NAVDD output capacitor should have a value of 10μ F or greater when the switching frequency is 2.1MHz and greater than 15μ F at 420kHz.

Setting the VG_{ON} and VG_{OFF} Output Voltages

Choose the external charge pump circuitry based on the ratios VG_{ON} /HVINP and VG_{OFF} /HVINP. In all cases, the VG_{ON} and VG_{OFF} voltages should be maintained within their permitted operating ranges.

The VG_{ON} and VG_{OFF} voltages are set by writing 6-bit values to the VG_{ON} (0x14) and VG_{OFF} (0x15) registers. Note that the VG_{ON} voltage range depends on the setting of dis_navdd bit.

LED Driver Section

DC-DC Converter for LED Driver

Two different converter topologies are possible with the DC-DC controller in the device, which has the ground-referenced outputs necessary to use the constant-current sink drivers. If the LED string forward voltage is always higher than the input supply voltage range, use the boost-converter topology. If the LED string forward voltage falls within the supply-voltage range, use the SEPIC topology.

Note that the boost converter topology provides the highest efficiency.

Power-Circuit Design

First select a converter topology based on the above factors. Determine the required input supply-voltage range, the maximum voltage needed to drive the LED strings, including the worst-case 0.875V across the constant LED current sink (V_{LED}), and the total output current needed to drive the LED strings (I_{LED}) as follows:

$I_{\text{LED}} = I_{\text{STRING}} \times N_{\text{STRING}}$

where I_{STRING} is the LED current per string in amperes and N_{STRING} is the number of strings used. Calculate the maximum duty cycle (D_{MAX}) using the following equations:

Boost Configuration:

$$D_{\text{MAX}} = \frac{\left(V_{\text{LED}} + V_{D1} - V_{\text{IN}} - M_{\text{IN}}\right)}{\left(V_{\text{LED}} + V_{D1} - V_{\text{DS}} - 0.42\right)}$$

SEPIC Configuration:

$$D_{\text{MAX}} = \frac{\left(V_{\text{LED}} + V_{D1}\right)}{\left(V_{\text{IN}_{\text{MIN}}} - V_{\text{DS}} - 0.42 + V_{\text{LED}} + V_{D1}\right)}$$

where V_{D1} is the forward drop of the rectifier diode in volts (approximately 0.6V), V_{IN_MIN} is the minimum input supply voltage in volts, V_{DS} is the drain-to-source voltage of the external MOSFET in volts when it is on, and 0.42V is the peak current-sense voltage. Initially, use an approximate value of 0.2V for V_{DS} to calculate D_{MAX} . Calculate a more accurate value of D_{MAX} after the power MOSFET is selected based on the maximum inductor current.

Boost Configuration

The average inductor current varies with the line voltage, and the maximum average current occurs at the lowest line voltage. For the boost converter, the average inductor current is equal to the input current. Select the maximum peak-to-peak ripple on the inductor current (ΔI_L). The recommended peak-to-peak ripple is 60% of the average inductor current.

Use the following equations to calculate the maximum average inductor current (IL_{AVG}) and peak inductor current (IL_P) in amperes.

$$IL_{AVG} = \frac{I_{LED}}{1 - D_{MAX}}$$

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Allowing the peak-to-peak inductor ripple (ΔI_L) to be ±30% of the average inductor current:

 $\Delta I_L = IL_{AVG} \times 0.3 \times 2$

and

 $IL_P = IL_{AVG} + \frac{\Delta I_L}{2}$

Calculate the minimum inductance value (L_{MIN}) in henries with the inductor-current ripple set to the maximum value.

$$L_{\text{MIN}} = \frac{\left(V_{\text{IN}} - M_{\text{DS}} - 0.41\right) \times D_{\text{MAX}}}{f_{\text{SW}} \times \Delta I_{L}}$$

where 0.41V is the peak current-sense voltage (with bl_ilim set to 0, if bl_ilim is set to 1 use 0.3V in this equation). Choose an inductor that has a minimum inductance greater than the calculated L_{MIN} and current rating greater than ILP. The recommended saturation current limit of the selected inductor is 10% higher than the inductor peak current for boost configuration.

SEPIC Configuration

Power-circuit design for the SEPIC configuration is very similar to a conventional design, with the output voltage referenced to the input supply voltage. For SEPIC, the output is referenced to ground and the inductor is split into two parts (see the SEPIC Application Circuit). One of the inductors (L2) has the LED current as the average current, and the other inductor (L1) has the input current as its average current. Use the following equations to calculate the average inductor currents (IL1_{AVG}, IL2_{AVG}) and peak inductor currents (IL1_P, IL2_P) in amperes:

$$IL1_{AVG} = \frac{I_{LED} \times D_{MAX} \times 1.1}{1 - D_{MAX}}$$

The factor 1.1 provides a 10% margin to account for the converter losses:

 $IL2_{AVG} = I_{LED}$

Assuming the peak-to-peak inductor ripple (ΔI_L) is ±30% of the average inductor current:

 $\Delta I_{L1} = IL1_{AVG} \times 0.3 \times 2$

and

 $|L1_P = |L1_{AVG} + \frac{\Delta I_{L1}}{2}$

 $\Delta I_{L2} = IL2_{AVG} \times 0.3 \times 2$

and

$$\mathsf{IL2}_P = \mathsf{IL2}_{\mathsf{AVG}} + \frac{\Delta \mathsf{I}_{L2}}{2}$$

Calculate the minimum inductance values $L1_{MIN}$ and $L2_{MIN}$ in henries with the inductor current ripples set to the maximum value as follows:

$$L1_{\text{MIN}} = \frac{\left(V_{\text{IN}}_{\text{MIN}} - V_{\text{DS}} - 0.42\right) \times D_{\text{MAX}}}{f_{\text{SW}} \times \Delta I_{L1}}$$
$$L2_{\text{MIN}} = \frac{\left(V_{\text{IN}}_{\text{MIN}} - V_{\text{DS}} - 0.42\right) \times D_{\text{MAX}}}{f_{\text{SW}} \times \Delta I_{L2}}$$

where 0.42V is the peak current-sense voltage. Choose inductors that have a minimum inductance greater than the calculated $L1_{MIN}$ and $L2_{MIN}$, and current ratings greater than $IL1_P$ and $IL2_P$, respectively. The recommended saturation current limit of the selected inductor is 10% higher than the inductor peak current.

For simplifying further calculations, consider L1 and L2 as a single inductor with L1/L2 connected in parallel. The combined inductance value and current is calculated as follows:

$$L_{\rm MIN} = \frac{L_{\rm MIN} \times L_{\rm MIN}}{L_{\rm MIN} + L_{\rm MIN}^2}$$

and

 $IL_{AVG} = IL1_{AVG} + IL2_{AVG}$

where IL_{AVG} represents the total average current through both the inductors, connected together for SEPIC configuration. Use these values in the calculations for the SEPIC configuration in the following sections.

Select coupling capacitor CS so that the peak-to-peak ripple on it is less than 2% of the minimum input supply voltage. This ensures that the second-order effects created by the series resonant circuit comprising L1, CS, and L2 do not affect the normal operation of the converter. Use the following equation to calculate the minimum value of CS:

$$CS \ge \frac{I_{LED} \times D_{MAX}}{V_{IN} MIN \times 0.02 \times f_{SW}}$$

where CS is the minimum value of the coupling capacitor in farads, I_{LED} is the LED current in amperes, and the factor 0.02 accounts for 2% ripple.

Current-Sense Resistor and Slope Compensation

The MAX25069 backlight boost generates a current ramp for slope compensation. This ramp current is synchronized to the switching frequency, starting from zero at the beginning of every clock cycle and rising linearly to reach 50 μ A at the end of the clock cycle. The slope-compensating resistor (R_{SC}) is connected between the CSP input and the source of the external MOSFET. This adds a programmable ramp voltage to the CSP input voltage to provide slope compensation.

Use the following equations to calculate the value of slope-compensation resistance (R_{SC}):

Boost Configuration:

$$R_{\rm SC} = \frac{(V_{\rm LED} - 2 \times V_{\rm IN} MIN) \times R_{\rm CS} \times 3}{L_{\rm MIN} \times 50 \mu A \times f_{\rm SW} \times 4}$$

SEPIC and Coupled-Inductor Configurations:

$$R_{\rm SC} = \frac{(V_{\rm LED} - V_{\rm IN}_{\rm MIN}) \times R_{\rm CS} \times 3}{L_{\rm MIN} \times 50 \mu \text{A} \times f_{\rm SW} \times 4}$$

where V_{LED} and V_{IN_MIN} are in volts, R_{SC} and R_{CS} are in ohms, L_{MIN} is in henries, and f_{SW} is in hertz. The value of the switch current-sense resistor (R_{CS}) can be calculated as follows:

Boost Configuration:

$$R_{\rm CS} = \frac{4 \times L_{\rm MIN} \times f_{\rm SW} \times V_{\rm CS} \text{ MAX} \times 0.9}{I_{\rm LP} \times 4 \times L_{\rm MIN} \times f_{\rm SW} + D_{\rm MAX} \times (V_{\rm LED} - 2 \times V_{\rm IN} \text{ MIN}) \times 3}$$

SEPIC and Coupled-Inductor Configurations:

$$R_{\text{CS}} = \frac{4 \times L_{\text{MIN}} \times f_{\text{SW}} \times V_{\text{CS}}_{\text{MAX}} \times 0.9}{I_{\text{LP}} \times 4 \times L_{\text{MIN}} \times f_{\text{SW}} + D_{\text{MAX}} \times (V_{\text{LED}} - V_{\text{IN}}_{\text{MIN}}) \times 3}$$

where V_{CS_MAX} is the minimum value of the peak current-sense threshold or 0.38 with bl_ilim = 0 and 0.275 when bl_ilim is set to 1. The current-sense threshold also includes the slope-compensation component. The minimum current-sense threshold is multiplied by 0.9 to take tolerances into account.

Output Capacitor Selection

For all converter topologies, the output capacitor supplies the load current when the main switch is on. The function of the output capacitor is to reduce the converter output ripple to acceptable levels. The entire output-voltage ripple appears across the constant-current sink outputs because the LED string voltages are stable due to the constant current. For the MAX25069, limit the peak-to-peak output-voltage ripple to 250mV to get stable output current.

The ESR, ESL, and bulk capacitance of the output capacitor contribute to the output ripple. In most applications, using low-ESR ceramic capacitors can dramatically reduce the output ESR and ESL effects, connecting multiple ceramic

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capacitors in parallel to achieve the required bulk capacitance. To minimize audible noise during PWM dimming however, it may be desirable to limit the use of ceramic capacitors on the boost output. In such cases, an additional electrolytic or tantalum capacitor can provide the majority of the bulk capacitance.

External Switching-MOSFET Selection

The external switching MOSFET should have a voltage rating sufficient to withstand the maximum boost output voltage, together with the rectifier diode drop and any possible overshoot due to ringing caused by parasitic inductance and capacitance. The recommended MOSFET V_{DS} voltage rating is 30% higher than the sum of the maximum output voltage and the rectifier diode drop.

The continuous drain-current rating of the MOSFET (ID), when the case temperature is at the maximum operating ambient temperature, should be greater than that calculated as follows:

$$ID_{RMS} = \left(\sqrt{IL_{AVG}^2 \times D_{MAX}}\right) \times 1.3$$

The MOSFET dissipates power due to both switching losses and conduction losses. Use the following equation to calculate the conduction losses in the MOSFET:

$P_{\text{COND}} = \text{IL}^2_{\text{AVG}} \times D_{\text{MAX}} \times R_{\text{DS(ON)}}$

where R_{DS(ON)} is the on-state drain-to-source resistance of the MOSFET. Use the following equation to calculate the switching losses in the MOSFET:

$$P_{\text{SW}} = \frac{IL_{\text{AVG}} \times V_{\text{LED}}^2 \times C_{\text{GD}} \times f_{\text{SW}}}{2} \times \left(\frac{1}{I_{\text{GON}}} + \frac{1}{I_{\text{GOFF}}}\right)$$

where I_{GON} and I_{GOFF} are the gate currents of the MOSFET in amperes when it is turned on and turned off, respectively. C_{GD} is the gate-to-drain MOSFET capacitance in farads.

Rectifier Diode Selection

Using a Schottky rectifier diode produces less forward drop and puts the least burden on the MOSFET during reverse recovery. A diode with considerable reverse-recovery time increases the MOSFET switching loss. Select a Schottky diode with a voltage rating 20% higher than the maximum boost-converter output voltage and current rating greater than the following:

$$I_D = IL_{AVG} \times (1 - D_{MAX}) \times 1.2$$

Feedback Compensation

During normal operation, the feedback control loop regulates the minimum OUT_ voltage to fall within the window comparator limits of 0.58V and 0.85V when LED string currents are enabled during PWM dimming. When LED currents are off during PWM dimming, the control loop turns off the converter. When the PWM dimming pulses are narrower than 50µs, the converter operates continuously.

The worst-case condition for the feedback loop is when the LED driver is in normal mode regulating the minimum OUT_voltage. The switching converter small-signal transfer function has a right-half plane (RHP) zero for boost configuration if the inductor current is in continuous-conduction mode. The RHP zero adds a 20dB/decade gain and a 90° phase lag, which is difficult to compensate.

The worst-case RHP zero frequency (f_{ZRHP}) is calculated as follows:

Boost Configuration:

$$f_{ZRHP} = \frac{V_{LED} \times (1 - D_{MAX})^2}{2\pi \times L \times I_{LED}}$$

SEPIC Configuration:

$$f_{ZRHP} = \frac{V_{LED} \times (1 - D_{MAX})^2}{2\pi \times L \times I_{LED} \times D_{MAX}}$$

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where f_{ZRHP} is in hertz, V_{LED} is in volts, L is the inductance value of L1 in henries, and I_{LED} is in amperes. A simple way to avoid this zero is to roll off the loop gain to 0dB at a frequency less than 1/5 of the RHP zero frequency with a -20dB/ decade slope.

The switching converter small-signal transfer function also has an output pole. The effective output impedance, together with the output filter capacitance, determines the output pole frequency (f_{P1}), calculated as follows:

Boost Configuration:

$$f_{P1} = \frac{I_{\text{LED}}}{2\pi \times V_{\text{LED}} \times C_{\text{OUT}}}$$

SEPIC Configuration:

 $f_{P1} = \frac{I_{\text{LED}} \times D_{\text{MAX}}}{2\pi \times V_{\text{LED}} \times C_{\text{OUT}}}$

where f_{P1} is in hertz, V_{LED} is in volts, I_{LED} is in amperes, and C_{OUT} is in farads. Compensation components (R_{COMP} and C_{COMP}) perform two functions: C_{COMP} introduces a low-frequency pole that presents a -20dB/ decade slope to the loop gain, and R_{COMP} flattens the gain of the error amplifier for frequencies above the zero formed by R_{COMP} and C_{COMP} . For compensation, this zero is placed at the output pole frequency (f_{P1}), so it provides a -20dB/decade slope for frequencies above f_{P1} to the combined modulator and compensator response.

The value of R_{COMP} needed to fix the total loop gain at f_{P1} , so the total loop gain crosses 0dB with -20dB/decade slope at 1/5 the RHP zero frequency, is calculated as follows:

Boost Configuration:

$$R_{\text{COMP}} = \frac{f_{\text{ZRHP}} \times R_{\text{CS}} \times I_{\text{LED}}}{5 \times f_{P1} \times GM_{\text{COMP}} \times V_{\text{LED}} \times (1 - D_{\text{MAX}})}$$

SEPIC Configuration:

$$R_{\text{COMP}} = \frac{f_{\text{ZRHP}} \times R_{\text{CS}} \times I_{\text{LED}} \times D_{\text{MAX}}}{5 \times f_{P1} \times GM_{\text{COMP}} \times V_{\text{LED}} \times (1 - D_{\text{MAX}})}$$

where R_{COMP} is the compensation resistor in ohms, f_{ZRHP} and f_{P2} are in hertz, R_{CS} is the switch current-sense resistor in ohms, and GM_{COMP} is the transconductance of the error amplifier (700µS).

The value of C_{COMP} is calculated as follows:

$$C_{\text{COMP}} = \frac{1}{2\pi \times R_{\text{COMP}} \times f_{Z1}}$$

where f_{Z1} is the compensation zero placed at 1/5 of the crossover frequency that is, in turn, set at 1/5 of the f_{ZRHP} . If the output capacitors do not have low ESR, the ESR zero frequency may fall within the 0dB crossover frequency. An additional pole may be required to cancel out this pole placed at the same frequency. This can be implemented by connecting a capacitor from COMP directly to GND.

Using NV Memory

Follow the sequence below to perform nonvolatile programming of the device when the autorefresh function is not used:

- 1. Apply a voltage between 3.3V and 5V to the IN and INN pins with the device in full I²C mode.
- 2. Write the desired values to be stored in OTP to the registers from 0x07 to 0x15.
- 3. Apply 8.5V to VPROG.
- 4. Optionally wait to ensure the 8.5V at V_{PROG} is stable.
- 5. Send burn_otp_reg (write 0xA5 to register address 0x78) command. If parity is enabled, ensure the overall parity is even by altering the final byte if necessary.
- 6. Wait 20ms.
- 7. If the nv_fit bit is 0, the write was successful; go to the next step. If nv_fit = 1, perform retry (steps 5 and 6).
- 8. Send reboot_otp (write 0x5A to register address 0x79) command or power-cycle the part.

Special care is required when performing nonvolatile programming with the autorefresh feature enabled. In such cases,

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follow the sequence below when at least one calibration has already been performed:

- 1. Apply a voltage between 3.3V and 5V to the IN and INN pins with the device in full I²C mode.
- 2. Set REG_CTRL[6] = 1. This dis_refresh bit inhibits refresh during programming operations.
- 3. Write the desired data to volatile registers.
- 4. Apply 8.5V to V_{PROG}.
- 5. Send the burn_otp_reg (write 0xA5 to 0x78) command.
- 6. Wait 20ms.
- 7. If the nv_flt bit is 0, the write was successful; go to the next step. If nv_flt = 1, perform retry (steps 5 and 6).
- 8. Send reboot_otp (write 0x5A to register address 0x79) command or power-cycle the part.
- 9. Check/set REG_CTRL[6] = 0.

The nonvolatile memory can be written to a total of six times.

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Typical Application Circuit

Typical Application Circuit


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Typical Application Circuit (continued)

SEPIC Application Circuit



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Ordering Information

PART	TEMP RANGE	PACKAGE CODE	PIN-PACKAGE	7-BIT I ² C ADDRESS
MAX25069ATM/V+	-40°C to +125°C	T4877+9C	48 TQFN-EP*	0x4E/0x4F
MAX25069ATM/VY+**	-40°C to +125°C	T4877Y+9C	48 TQFN-EP*	0x4E/0x4F

N Denotes an automotive-qualified part.

+Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

*EP = Exposed pad.

Y = Side-wettable (SW) package

**Future product—contact factory for availability.

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Revision History

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
0	11/22	Initial release	—



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